ADVANCE INFORMATION



CC1354R10 SimpleLink™ 高性能マルチバンド・ワイヤレス・マイコン

1 特長

ワイヤレス・マイクロコントローラ

- 強力な 48MHz Arm[®] Cortex[®]-M33 プロセッサと TrustZone®の組み合わせ
- FPUとDSPの拡張機能
- 1024kB フラッシュ・プログラム・メモリ
- 8kB のキャッシュ SRAM
- 高信頼性動作に適した 256kB の超低リーク SRAM (パリティ付き)
 - - パリティが無効になっている場合は 32kB の SRAM を追加可能
- デュアル・バンド Sub-1GHz および 2.4GHz 動作
- ダイナミック・マルチプロトコル・マネージャ (DMM) ドラ イバ
- プログラマブルな無線機能には、2-(G)FSK、4-(G)FSK, MSK, OOK, IEEE 802.15.4 PHY, MAC のサポートが含まれます。
- OTA (Over-The-Air) アップグレードに対応

超低消費電力センサ・コントローラ

- 4kBの SRAM を備えた自律型 MCU
- センサ・データのサンプリング、保存、処理
- 高速ウェークアップによる低消費電力動作
- ソフトウェア定義ペリフェラル、静電容量式タッチ、流量 計、LCD

低い消費電力

- MCU の消費電流:
 - 3.4mA (アクティブ・モード、CoreMark[®])
 - 71µA/MHz (CoreMark 実行中)
 - 0.98µA (スタンバイ・モード、RTC、256kB RAM)
 - 0.17μA (シャットダウン・モード、ウェークアップ・オ ン・ピン)
- 超低消費電力センサ・コントローラの消費電流
 - 32µA (2MHz モード)
 - 820µA (24MHz モード)
- 無線の消費電流:
 - 5.8mA (RX, 868MHz)
 - 6.9mA (RX, 2.4GHz)
 - 25.8mA (TX、+14dBm、868MHz)

無線プロトコルのサポート

- Thread, Zigbee®, Matter
- Bluetooth® 5.3 Low Energy
- Wi-SUN® •
- **MIOTY®**
- Amazon Sidewalk

- ワイヤレス M-Bus
- SimpleLink™ TI 15.4 スタック (Sub-1GHz)
- 6LoWPAN
- 独自システム

高性能の無線

- –121dBm (2.5kbps、長距離モード)
- -110dBm (50kbps, 802.15.4, 868MHz)
- -104dBm (Bluetooth® Low Energy, 125kbps)
- -105dBm (IEEE 802.15.4-2006 2.4GHz OQPSK) コヒーレント・モデム)

法規制の順守

- 以下の規格への準拠を目的としたシステムに最適:
 - ETSI EN 300 220 Receiver Cat. 1.5 および 2、 EN 300 328, EN 303 131, EN 303 204, EN 300 440 Cat.2 および 3
 - FCC CFR47 Part 15
 - ARIB STD-T66、STD-T67、STD-T108

MCU のペリフェラル

- ほとんどのデジタル・ペリフェラルを任意の GPIO に配 線可能
- 4 つの 32 ビットまたは 8 つの 16 ビット汎用タイマ
- 12 ビット SAR ADC、200ksps、8 チャネル
- 8 ビット DAC
- 2つのコンパレータ
- プログラマブル電流ソース
- 4 つの UART、4 つの SPI、2 つの I²C、I²S
- リアルタイム・クロック(RTC)
- 温度およびバッテリ・モニタを内蔵

セキュリティを実現する機能

- セキュア・ブートのサポート
- セキュア・キー・ストレージとデバイス ID をサポート
- 信頼できる実行環境に対応する Arm TrustZone
- AES 128 および 256 ビット暗号化アクセラレータ
- 公開鍵アクセラレータ
- SHA2 アクセラレータ (SHA-512 までのフル・スイート)
 - TRNG (True Random Number Generator)
- セキュア・デバッグ・ロック
- ソフトウェア・アンチロールバック保護

開発ツールとソフトウェア

- 868/915MHz でのデュアルバンドおよび 20dBm 出力 電力用の LP-EM-CC1354P10-1
- 2.4GHz でのデュアルバンドおよび 10dBm 出力電力 用の LP-EM-CC1354P10-6

英語版のTI製品についての情報を翻訳したこの資料は、製品の概要を確認する目的で便宜的に提供しているものです。該当する正式な英語版の最新情報は、 🐼 www.ti.com で閲覧でき、その内容が常に優先されます。 TI では翻訳の正確性および妥当性につきましては一切保証いたしません。 実際の設計などの前には、必ず 最新版の英語版をご参照くださいますようお願いいたします。



- LP-XDS110、LP-XDS110ET または TMDSEMU110-U (TMDSEMU110-ETH アドオン使用) デバッグ・プロ ーブ
- SimpleLink™ LOWPOWER F2 ソフトウェア開発キット (SDK)
- SmartRF[™] Studio による簡素な無線構成
- Sensor Controller Studio により低消費電力のセンシング・アプリケーションを構築
- SysConfig システム・コンフィギュレーション・ツール

動作範囲

- オンチップの降圧型 DC/DC コンバータ
- 1.8V~3.8Vの単一電源電圧
- -40°C∼+105°C

パッケージ

- 7mm × 7mm RGZ VQFN48 (GPIO 28 本)
- 8mm × 8mm RSK VQFN64 (GPIO 42 本)¹
- RoHS 準拠のパッケージ

2 アプリケーション

- 315、433、470~510、868、902~928、
 2400~2480MHz の ISM および SRD システム² (最小 4kHz の受信帯域幅)
- ビルディング・オートメーション
 - ビルディングのセキュリティ・システム モーション検 出器、電子スマート・ロック、ドアおよび窓センサ、ガ レージ・ドア・システム、ゲートウェイ

- WWW.ti.com/ja
 HVAC サーモスタット、ワイヤレス環境センサ、
 HVAC システム・コントローラ、ゲートウェイ
- 防火システム 煙および熱感知器、火災警報制御
 パネル (FACP)
- ビデオ監視 IP ネットワーク・カメラ
- エレベータとエスカレータ-エレベータとエスカレー
 タのエレベータ・メイン制御パネル
- グリッド・インフラストラクチャ
 - スマート・メータ 水道メータ、ガス・メータ、電気メ
 ータ、ヒート・コスト・アロケータ
 - グリッド通信 無線通信 長距離センサ・アプリケ ーション
- その他の代替エネルギー-環境発電
- 産業用輸送 アセット・トラッキング
- ファクトリ・オートメーションおよび制御
- 医療用
- 通信機器
 - 有線ネットワーク ワイヤレス LAN または Wi-Fi ア クセス・ポイント、エッジ・ルーター
- ・ パーソナル・エレクトロニクス
 - ホーム・シアターおよびエンターテインメント スマ
 ート・スピーカ、スマート・ディスプレイ、セット・トップ・ボックス
 - ウェアラブル (非医療用) スマート・トラッカー、ス マート衣料

3 概要

ADVANCE INFORMATION

SimpleLink[™] CC1354R10 デバイスはマルチプロトコル、マルチバンドの Sub-1GHz および 2.4GHz ワイヤレス・マイコ ン (MCU) です。本デバイスは Thread、Zigbee[®]、Bluetooth 5.3 Low Energy、IEEE 802.15.4g、IPv6 対応スマート・オ ブジェクト (6LoWPAN)、MIOTY、Wi-SUN、Amazon Sidewalk、TI 15.4 スタック (Sub-1GHz および 2.4GHz) を含む独 自システム、DMM (ダイナミック・マルチプロトコル・マネージャ)ドライバを使った同時マルチプロトコルをサポートしていま す。本デバイスは低消費電力のワイヤレス通信向けに最適化されており、高度なセキュリティ機能とオンチップのワイヤレ ス更新機能を備えています。本デバイスは、ビルディングのセキュリティ・システム、HVAC、スマート・メータ、医療、有線ネ ットワーク、携帯型電子機器、ホーム・シアター / エンターテインメント、ネットワーク接続周辺機器市場向けの長距離かつ 信頼性の高い通信を可能にします。このデバイスの主な特長を以下に示します

- Arm® TrustZone® ベースのセキュア・キー・ストレージ、デバイス ID、トラステッド機能をサポート。
- DMM ドライバを使用して、Sub-1GHz と 2.4GHz の両方の同時マルチプロトコルをサポートするマルチバンド・デバイス。
- SimpleLink LOWPOWER F2 ソフトウェア開発キット (SDK) で幅広いプロトコル・スタックを柔軟にサポート。
- 0.83µA の小さいスタンバイ電流 (全 RAM 保持) により、ワイヤレス・アプリケーションのバッテリ寿命を延長。
- ・ 産業用温度に対応し、85℃で 5µA の最小スタンバイ電流。
- 高速ウェークアップ機能を備えたプログラマブルな自律型超低消費電力センサ・コントローラ CPU による高度なセンシング。たとえば、このセンサ・コントローラは、1µA のシステム電流で 1Hz の ADC サンプリングが可能です。
- 潜在的な放射線イベントによるデータ破損を防止する常時オン SRAM パリティを備え、低い SER (ソフト・エラー・レート) FIT (Failure-in-time、故障率) により、産業用市場向けに中断のない長い動作寿命を実現。



¹ RSK パッケージ (8.00mm × 8.00mm) に関する情報はプレビューについてのものであり、変更される可能性があります。

² サポートしているプロトコル規格、変調フォーマット、データ・レートの詳細については、RF コアを参照してください。



- 柔軟性の高い低消費電力 RF トランシーバ機能を備えた専用のソフトウェア制御無線コントローラ (Arm[®] Cortex[®]-M0) により、複数の物理層および RF 規格をサポート。
- SimpleLink 長距離モードに対応する優れた無線感度 (-121dBm) と堅牢 (選択度、ブロッキング) 性能。

CC1354R10 デバイスは、SimpleLink[™] MCU プラットフォームの一部です。本プラットフォームは、単一のコア SDK (ソ フトウェア開発キット) と豊富なツール・セットを備えた使いやすい共通の開発環境を共有する Wi-Fi®、Bluetooth Low Energy、Thread、Zigbee、Sub-1GHz MCU、およびホスト MCU で構成されています。SimpleLink プラットフォームの 統合を 1 回行うだけで、どのようなデバイスの組み合わせでも、ポートフォリオから自分の設計に追加でき、設計の要件が 変化した場合でも、コードを 100% 再利用することができます。詳細については、「SimpleLink MCU プラットフォーム」を 参照してください。

ソフトウェアの互換性に加えて、マルチバンド・ワイヤレス MCU は 7 × 7mm の QFN パッケージに封止済みで、352kB のフラッシュから 1MB のフラッシュまでのピン互換性があるので、設計のスケーラビリティを最大限に高めることができます。テキサス・インスツルメンツ の Sub-1GHz ソリューションの詳細については、www.ti.com/sub1ghz を参照してください。

部品番号(1)	パッケージ	本体サイズ (公称)						
CC1354R106T0RGZ	VQFN (48)	7.00mm × 7.00mm						
CC1354R106T0RSK	VQFN (64)	8.00mm × 8.00mm						

制品情報

(1) 提供中の全デバイスに関する最新の製品、パッケージ、および注文情報については、セクション 12 のパッケージ・オプションに関する付録、また

はテキサス・インスツルメンツの Web サイトを参照してください。



4 Functional Block Diagram

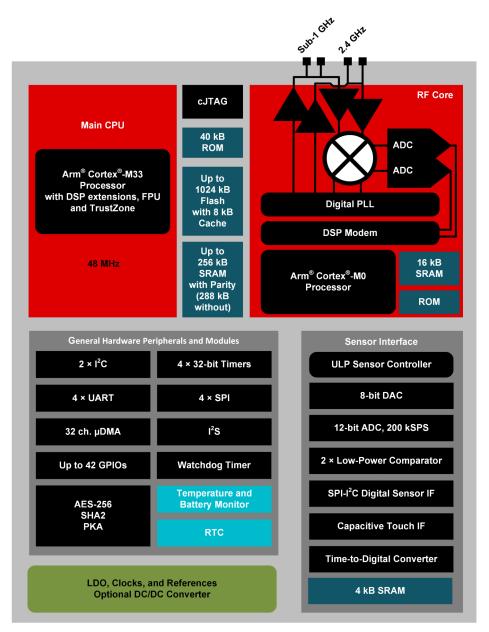


図 4-1. CC1354R10 Block Diagram



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5 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from December 8, 2022 to June 19, 2023 (from Revision * (December 2022) to Revision A (June 2023))

Revision A (June 2023))	Page
Updated Functional Block Diagram	
Added devices to the Device Comparison table	
• Deleted device revision limitation for LQI in 表 9-1	
Updated cryptography description	
Updated links in the Reference Designs	



6 Device Comparison

		RADIO SUPPORT													PACKAGE SIZE					
Device	Sub-1 GHz Prop.	2.4GHz Prop.	Wireless M-Bus	mioty	Wi-SUN®	Sidewalk	Bluetooth® LE	ZigBee	Thread	Multiprotocol	+20 dBm PA	FLASH (kB)	RAM + Cache (kB)	GPIO	4 × 4 mm VQFN (24)	4 × 4 mm VQFN (32)	5 × 5 mm VQFN (32)	5 × 5 mm VQFN (40)	7 × 7 mm VQFN (48)	8 × 8 mm VQFN (64)
CC1310	√		\checkmark	\checkmark								32-128	16-20 + 8	10-30		\checkmark	\checkmark		\checkmark	
CC1311R3	\checkmark		\checkmark	\checkmark								352	32 + 8	22-30				\checkmark	\checkmark	
CC1311P3	\checkmark		\checkmark	\checkmark							\checkmark	352	32 + 8	26					\checkmark	
CC1312R	\checkmark		\checkmark	\checkmark	\checkmark							352	80 + 8	30					\checkmark	
CC1312R7	\checkmark		\checkmark	\checkmark	\checkmark	\checkmark				\checkmark		704	144 + 8	30					\checkmark	
CC1314R10	\checkmark		\checkmark	\checkmark	\checkmark	\checkmark				\checkmark		1024	256 + 8	30-46					\checkmark	\checkmark
CC1352R	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark		\checkmark	\checkmark	\checkmark	\checkmark		352	80 + 8	28					\checkmark	
CC1354R10	V	\checkmark	\checkmark	\checkmark	\checkmark		\checkmark	V	\checkmark	\checkmark		1024	256 + 8	28-42					\checkmark	\checkmark
CC1352P	\checkmark	V	\checkmark	\checkmark	\checkmark		V	\checkmark	\checkmark		\checkmark	352	80 + 8	26					\checkmark	
CC1352P7	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	704	144 + 8	26					\checkmark	
CC1354P10	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	1024	256 + 8	26-42					\checkmark	\checkmark
CC2340R2		V					V	\checkmark				256	28	12						
CC2340R5		\checkmark					\checkmark	\checkmark	\checkmark			512	36	12-26				\checkmark		
CC2340R5-Q1							V					512	36	19			\checkmark			
CC2640R2F							\checkmark					128	20 + 8	10-31		\checkmark	\checkmark		\checkmark	
CC2642R							\checkmark					352	80 + 8	31					\checkmark	
CC2642R-Q1							\checkmark					352	80 + 8	31					\checkmark	
CC2651R3		\checkmark					\checkmark	\checkmark				352	32 + 8	23-31				\checkmark	\checkmark	
CC2651P3		\checkmark					\checkmark	\checkmark			\checkmark	352	32 + 8	22-26				\checkmark	\checkmark	
CC2652R		\checkmark					\checkmark	\checkmark	\checkmark	\checkmark		352	80 + 8	31					\checkmark	
CC2652RB		\checkmark					\checkmark	\checkmark	\checkmark	\checkmark		352	80 + 8	31					\checkmark	
CC2652R7		\checkmark					\checkmark	\checkmark	\checkmark			704	144 + 8	31					\checkmark	
CC2652P		\checkmark					\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	352	80 + 8	26					\checkmark	
CC2652P7		\checkmark						\checkmark	\checkmark	\checkmark	\checkmark	704	144 + 8	26					\checkmark	
CC2674R10		\checkmark					\checkmark	\checkmark	\checkmark	\checkmark		1024	256 + 8	31-45					\checkmark	\checkmark
CC2674P10		\checkmark					\checkmark	\checkmark	\checkmark	\checkmark	\checkmark	1024	256 + 8	26-45					\checkmark	\checkmark



7 Terminal Configuration and Functions

7.1 Pin Diagram – RGZ Package (Top View)

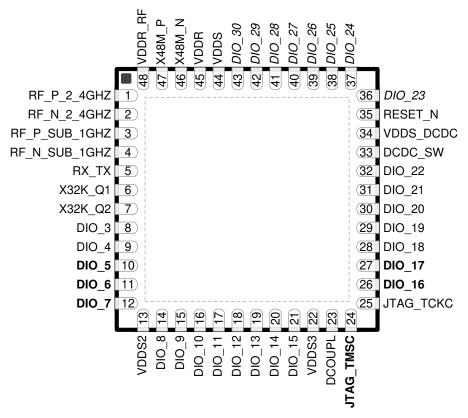


図 7-1. RGZ (7 mm × 7 mm) Pinout, 0.5 mm Pitch (Top View)

The following I/O pins marked in 🛛 7-1 in **bold** have high-drive capabilities:

- Pin 10, DIO_5
- Pin 11, DIO_6
- Pin 12, DIO_7
- Pin 24, JTAG_TMSC
- Pin 26, DIO_16
- Pin 27, DIO_17

The following I/O pins marked in 🗵 7-1 in *italics* have analog capabilities:

- Pin 36, DIO_23
- Pin 37, DIO 24
- Pin 38, DIO 25
- Pin 39, DIO_26
- Pin 40, DIO_27
- Pin 41, DIO_28
- Pin 42, DIO_29
- Pin 43, DIO_30

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7.2 Signal Descriptions – RGZ Package

表 7-1. Signal Descriptions – RGZ Package

PIN I/O TYPE NAME NO. I/O TYPE			TVDE	DESCRIPTION			
		ITPE	DESCRIPTION				
DCDC_SW	33	_	Power	Output from internal DC/DC converter ⁽¹⁾			
DCOUPL	23	_	Power	For decoupling of internal 1.27 V regulated digital-supply ⁽²⁾			
DIO_3	8	I/O	Digital	GPIO			
DIO_4	9	I/O	Digital	GPIO			
DIO_5	10	I/O	Digital	GPIO, high-drive capability			
DIO_6	11	I/O	Digital	GPIO, high-drive capability			
DIO_7	12	I/O	Digital	GPIO, high-drive capability			
DIO_8	14	I/O	Digital	GPIO			
DIO_9	15	I/O	Digital	GPIO			
DIO_10	16	I/O	Digital	GPIO			
DIO_11	17	I/O	Digital	GPIO			
DIO_12	18	I/O	Digital	GPIO			
DIO_13	19	I/O	Digital	GPIO			
DIO_14	20	I/O	Digital	GPIO			
DIO_15	21	I/O	Digital	GPIO			
DIO_16	26	I/O	Digital	GPIO, JTAG_TDO, high-drive capability			
DIO_17	27	I/O	Digital	GPIO, JTAG_TDI, high-drive capability			
DIO_18	28	I/O	Digital	GPIO			
DIO_19	29	I/O	Digital	GPIO			
DIO_20	30	I/O	Digital	GPIO			
DIO_21	31	I/O	Digital	GPIO			
DIO_22	32	I/O	Digital	GPIO			
DIO_23	36	I/O	Digital or Analog	GPIO, analog capability			
DIO_24	37	I/O	Digital or Analog	GPIO, analog capability			
DIO_25	38	I/O	Digital or Analog	GPIO, analog capability			
DIO_26	39	I/O	Digital or Analog	GPIO, analog capability			
DIO_27	40	I/O	Digital or Analog	GPIO, analog capability			
DIO_28	41	I/O	Digital or Analog	GPIO, analog capability			
DIO_29	42	I/O	Digital or Analog	GPIO, analog capability			
DIO_30	43	I/O	Digital or Analog	GPIO, analog capability			
EGP		_	GND	Ground – exposed ground pad ⁽³⁾			
JTAG_TMSC	24	I/O	Digital	JTAG TMSC, high-drive capability			
JTAG_TCKC	25	I	Digital	JTAG TCKC			
RESET_N	35	I	Digital	Reset, active low. No internal pullup resistor			
RF_P_SUB_1GHZ	3	_	RF	Positive Sub-1 GHz RF input signal to LNA during RX Positive Sub-1 GHz RF output signal from PA during TX			
RF_N_SUB_1GHZ	4	_	RF	Negative Sub-1 GHz RF input signal to LNA during RX Negative Sub-1 GHz RF output signal from PA during TX			
RX_TX	5	—	RF	Optional bias pin for the RF LNA			
VDDR	45	_	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO ^{(2) (4) (6)}			
VDDR_RF	48	_	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO ^{(2) (5) (6)}			
VDDS	44	—	Power	1.8 V to 3.8 V main chip supply ⁽¹⁾			

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表 7-1. Signal Descriptions – RGZ Package (continued)

PIN		I/O	ТҮРЕ	DESCRIPTION			
NAME	NO.	"0		DESCRIPTION			
VDDS2	13	_	Power	1.8 V to 3.8 V DIO supply ⁽¹⁾			
VDDS3	22	_	Power	1.8 V to 3.8 V DIO supply ⁽¹⁾			
VDDS_DCDC	34	_	Power	1.8 V to 3.8 V DC/DC converter supply			
X48M_N	46	_	Analog	48 MHz crystal oscillator pin N			
X48M_P	47	_	Analog	48 MHz crystal oscillator pin P			
X32K_Q1	6		Analog	32 kHz crystal oscillator pin 1			
X32K_Q2	7	_	Analog	32 kHz crystal oscillator pin 2			

(1) For more details, see technical reference manual listed in セクション 11.2.

(2) Do not supply external circuitry from this pin.

(3) EGP is the only ground connection for the device. Good electrical connection to device ground on printed circuit board (PCB) is imperative for proper device operation.

(4) If internal DC/DC converter is not used, this pin is supplied internally from the main LDO.

(5) If internal DC/DC converter is not used, this pin must be connected to VDDR for supply from the main LDO.

(6) Output from internal DC/DC and LDO is trimmed to 1.68 V.

7.3 Connections for Unused Pins and Modules – RGZ Package

FUNCTION	SIGNAL NAME	PIN NUMBER	ACCEPTABLE PRACTICE ⁽¹⁾	PREFERRED PRACTICE ⁽¹⁾				
GPIO	DIO_n	8–12 14–21 26–32 36–43	NC or GND	NC				
32.768 kHz crystal	X32K_Q1	6 8	NC or GND	NC				
	X32K_Q2	7		NC				
DC/DC converter ⁽²⁾	DCDC_SW	33	NC	NC				
	VDDS_DCDC	34	VDDS	VDDS				

表 7-2. Connections for Unused Pins - RGZ Package

(1) NC = No connect

(2) When the DC/DC converter is not used, the inductor between DCDC_SW and VDDR can be removed. VDDR and VDDR_RF must still be connected and the 22 µF DCDC capacitor must be kept on the VDDR net.

7.4 Pin Diagram – RSK Package (Top View)

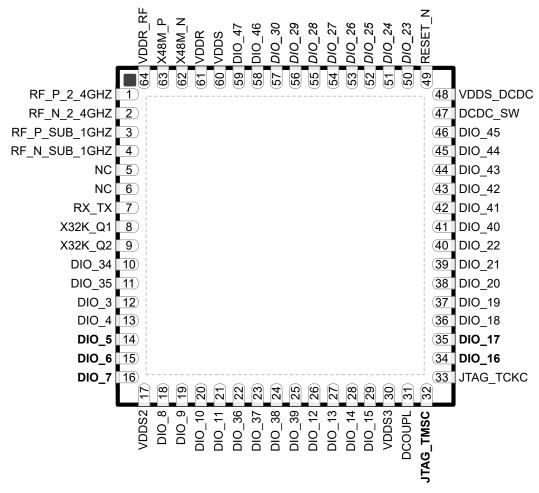


図 7-2. RSK (8 mm × 8 mm) Pinout, 0.4 mm Pitch (Top View)

The following I/O pins marked in \boxtimes 7-2 in **bold** have high-drive capabilities:

- Pin 14, DIO_5
- Pin 15, DIO_6
- Pin 16, DIO_7
- Pin 32, JTAG_TMSC
- Pin 34, DIO_16
- Pin 35, DIO_17

The following I/O pins marked in 🗵 7-2 in *italics* have analog capabilities:

- Pin 50, DIO_23
- Pin 51, DIO_24
- Pin 52, DIO_25
- Pin 53, DIO_26
- Pin 54, DIO_27
- Pin 55, DIO_28
- Pin 56, DIO_29
- Pin 57, DIO_30



7.5 Signal Descriptions – RSK Package

PIN		1/0	TY/D5	DESCRIPTION			
NAME	NO.	I/O	TYPE	DESCRIPTION			
DCDC_SW	47	_	Power	Output from internal DC/DC converter ⁽¹⁾			
DCOUPL	31	_	Power	For decoupling of internal 1.27 V regulated digital-supply ⁽²⁾			
DIO_3	12	I/O	Digital	GPIO			
DIO_4	13	I/O	Digital	GPIO			
DIO_5	14	I/O	Digital	GPIO, high-drive capability			
DIO_6	15	I/O	Digital	GPIO, high-drive capability			
DIO_7	16	I/O	Digital	GPIO, high-drive capability			
DIO_8	18	I/O	Digital	GPIO			
DIO_9	19	I/O	Digital	GPIO			
DIO_10	20	I/O	Digital	GPIO			
DIO_11	21	I/O	Digital	GPIO			
DIO_12	26	I/O	Digital	GPIO			
DIO_13	27	I/O	Digital	GPIO			
DIO_14	28	I/O	Digital	GPIO			
DIO_15	29	I/O	Digital	GPIO			
DIO_16	34	I/O	Digital	GPIO, JTAG_TDO, high-drive capability			
DIO_17	35	I/O	Digital	GPIO, JTAG_TDI, high-drive capability			
DIO_18	36	I/O	Digital	GPIO			
DIO_19	37	I/O	Digital	GPIO			
DIO_20	38	I/O	Digital	GPIO			
DIO_21	39	I/O	Digital	GPIO			
DIO_22	40	I/O	Digital	GPIO			
DIO_23	50	I/O	Digital or Analog	GPIO, analog capability			
DIO_24	51	I/O	Digital or Analog	GPIO, analog capability			
DIO_25	52	I/O	Digital or Analog	GPIO, analog capability			
DIO_26	53	I/O	Digital or Analog	GPIO, analog capability			
DIO_27	54	I/O	Digital or Analog	GPIO, analog capability			
DIO_28	55	I/O	Digital or Analog	GPIO, analog capability			
DIO_29	56	I/O	Digital or Analog	GPIO, analog capability			
DIO_30	57	I/O	Digital	GPIO, analog capability			
DIO_34	10	I/O	Digital	GPIO			
DIO_35	11	I/O	Digital	GPIO			
DIO_36	22	I/O	Digital	GPIO			
DIO_37	23	I/O	Digital	GPIO			
DIO_38	24	I/O	Digital	GPIO			
DIO_39	25	I/O	Digital	GPIO			
DIO_40	41	I/O	Digital	GPIO			
DIO_41	42	I/O	Digital	GPIO			
DIO_42	43	I/O	Digital	GPIO			
DIO_43	44	I/O	Digital	GPIO			
DIO_44	45	I/O	Digital	GPIO			
DIO_45	46	I/O	Digital	GPIO			

表 7-3. Signal Descriptions – RSK Package



表 7-3. Signal Descriptions – RSK Package (continued)

PIN		1/0	ТҮРЕ	DESCRIPTION			
NAME	NO.	1/0	ITFE	DESCRIPTION			
DIO_46	58	I/O	Digital	GPIO			
DIO_47	59	I/O	Digital	GPIO			
EGP	_	—	GND	Ground – exposed ground pad ⁽³⁾			
JTAG_TMSC	32	I/O	Digital	JTAG TMSC, high-drive capability			
JTAG_TCKC	33	I	Digital	JTAG TCKC			
RESET_N	49	I	Digital	Reset, active low. No internal pullup resistor			
RF_P_2_4GHZ	1	_	RF	Positive 2.4 GHz RF input signal to LNA during RX Positive 2.4 GHz RF output signal from PA during TX			
RF_N_2_4GHZ	2	_	RF	Negative 2.4 GHz RF input signal to LNA during RX Negative 2.4 GHz RF output signal from PA during TX			
RF_P_SUB_1GHZ	3	_	RF	Positive Sub-1 GHz RF input signal to LNA during RX Positive Sub-1 GHz RF output signal from PA during TX			
RF_N_SUB_1GHZ	4	_	RF	Negative Sub-1 GHz RF input signal to LNA during RX Negative Sub-1 GHz RF output signal from PA during TX			
RX_TX	7	—	RF	Optional bias pin for the RF LNA			
VDDR	61	_	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO ^{(2) (4) (6)}			
VDDR_RF	64	_	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO ^{(2) (5) (6)}			
VDDS	60	—	Power	1.8 V to 3.8 V main chip supply ⁽¹⁾			
VDDS2	17	—	Power	1.8 V to 3.8 V DIO supply ⁽¹⁾			
VDDS3	30	—	Power	1.8 V to 3.8 V DIO supply ⁽¹⁾			
VDDS_DCDC	48	—	Power	1.8 V to 3.8 V DC/DC converter supply			
X48M_N	62	_	Analog	48 MHz crystal oscillator pin N			
X48M_P	63	—	Analog	48 MHz crystal oscillator pin P			
NC	5	_	—	No connect			
NC	6	_	—	No connect			
X32K_Q1	8	_	Analog	32 kHz crystal oscillator pin 1			

(1) For more details, see technical reference manual listed in セクション 11.2.

(2) Do not supply external circuitry from this pin.

(3) EGP is the only ground connection for the device. Good electrical connection to device ground on printed circuit board (PCB) is imperative for proper device operation.

(4) If internal DC/DC converter is not used, this pin is supplied internally from the main LDO.

(5) If internal DC/DC converter is not used, this pin must be connected to VDDR for supply from the main LDO.

(6) Output from internal DC/DC and LDO is trimmed to 1.68 V.



7.6 Connection of Unused Pins and Module – RSK Package

FUNCTION	SIGNAL NAME	PIN NUMBER	ACCEPTABLE PRACTICE ⁽¹⁾	PREFERRED PRACTICE ⁽¹⁾	
GPIO	DIO_n	10–16 14–21 26–32 36–43	NC or GND	NC	
	X32K_Q1	8	- NC or GND	NC	
32.768 kHz crystal	X32K_Q2	9		INC.	
No Connects	NC	5–8	NC	NC	
DC/DC converter ⁽²⁾	DCDC_SW	47	NC	NC	
	VDDS_DCDC	48	VDDS	VDDS	

表 7-4. Connections for Unused Pins – RSK Package

(1) NC = No connect

(2) When the DC/DC converter is not used, the inductor between DCDC_SW and VDDR can be removed. VDDR and VDDR_RF must still be connected and the 22 µF DCDC capacitor must be kept on the VDDR net.



8 Specifications

8.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾ (2)

			MIN	MAX	UNIT
VDDS ⁽³⁾	Supply voltage		-0.3	4.1	V
	Voltage on any digital pin	(4) (5)	-0.3	VDDS + 0.3, max 4.1	V
	Voltage on crystal oscilla	tor pins, X32K_Q1, X32K_Q2, X48M_N and X48M_P	-0.3	VDDR + 0.3, max 2.25	V
	Voltage on ADC input	Voltage scaling enabled	-0.3	VDDS	
Vin		Voltage scaling disabled, internal reference	-0.3	1.49	V
		Voltage scaling disabled, VDDS as reference	-0.3	VDDS / 2.9	
	Input level, Sub-1 GHz R	F pins		10	dBm
	Input level, 2.4 GHz RF p	ins		5	dBm
T _{stg}	Storage temperature		-40	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to ground, unless otherwise noted.

(3) VDDS_DCDC, VDDS2 and VDDS3 must be at the same potential as VDDS.

(4) Including analog capable DIOs.

(5) Injection current is not supported on any GPIO pin

8.2 ESD Ratings

				VALUE	UNIT
V _{ESD} Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	All pins	±2000	V	
	Liecti Ostatic discharge	Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	All pins	±500	V

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process

(2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process

8.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Operating ambient temperature ^{(1) (3)}			105	°C
Operating supply voltage (VDDS)		1.8	3.8	V
Operating supply voltage (VDDS), boost mode	VDDR = 1.95 V +14 dBm RF output power	2.1	3.8	V
Rising supply voltage slew rate		0	100	mV/µs
Falling supply voltage slew rate ⁽²⁾		0	20	mV/μs

(1) Operation at or near maximum operating temperature for extended durations will result in lifetime reduction.

(2) For small coin-cell batteries, with high worst-case end-of-life equivalent source resistance, a 22 µF VDDS input capacitor must be used to ensure compliance with this slew rate.

(3) For thermal resistance characteristics refer to Thermal Resistance Characteristics. For application considerations, refer to SPRA953

8.4 Power Supply and Modules

Over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
VDDS Power-on-Reset (POR) threshold		1	1 - 1.55		V
VDDS Brown-out Detector (BOD) (1)	Rising threshold		1.77		V
VDDS Brown-out Detector (BOD), before initial boot ⁽²⁾	Rising threshold		1.70		V
VDDS Brown-out Detector (BOD) ⁽¹⁾	Falling threshold		1.75		V

(1) For boost mode (VDDR =1.95 V), TI drivers software initialization will trim VDDS BOD limits to maximum (approximately 2.0 V)



(2) Brown-out Detector is trimmed at initial boot, value is kept until device is reset by a POR reset or the RESET_N pin

8.5 Power Consumption - Power Modes

When measured on the LP-EM-CC1354P10-1 reference design with T_c = 25 °C, V_{DDS} = 3.6 V with DC/DC enabled unless otherwise noted.

	PARAMETER	TEST CONDITIONS	TYP	UNIT
Core Curre	nt Consumption			
	Reset and Shutdown	Reset. RESET_N pin asserted or VDDS below power-on-reset threshold	150	nA
		Shutdown. No clocks running, no retention	171	ΠA
		RTC running, CPU, 256 kB RAM and (partial) register retention. RCOSC_LF	0.98	μA
	Standby	RTC running, CPU, 128 kB RAM and (partial) register retention. RCOSC_LF	0.88	μA
	without cache retention	RTC running, CPU, 256 kB RAM and (partial) register retention XOSC_LF	1.08	μA
		RTC running, CPU, 128 kB RAM and (partial) register retention XOSC_LF	0.99	μA
I _{core}		RTC running, CPU, 256 kB RAM and (partial) register retention. RCOSC_LF	2.24	μA
	Standby	RTC running, CPU, 128 kB RAM and (partial) register retention. RCOSC_LF	2.16	μA
	with cache retention	RTC running, CPU, 256 kB RAM and (partial) register retention. XOSC_LF	2.34	μA
		RTC running, CPU, 128 kB RAM and (partial) register retention. XOSC_LF	2.25	μA
	Idle	Supply Systems and RAM powered RCOSC_HF	635	μA
	A - 45	MCU running CoreMark at 48 MHz with parity enabled RCOSC_HF	3.5	mA
	Active	MCU running CoreMark at 48 MHz with parity disabled RCOSC_HF	3.4	mA
Peripheral	Current Consumption	1	J	
	Peripheral power domain	Delta current with domain enabled	62.4	
	Serial power domain	Delta current with domain enabled	5.83	
	RF Core	Delta current with power domain enabled, clock enabled, RF core idle	102.0	
	μDMA	Delta current with clock enabled, module is idle	58.0	
	Timers	Delta current with clock enabled, module is idle ⁽³⁾	97.2	
peri	12C	Delta current with clock enabled, module is idle	9.8	μA
	12S	Delta current with clock enabled, module is idle	22.2	
	SPI	Delta current with clock enabled, module is idle ⁽²⁾	55.8	
	UART	Delta current with clock enabled, module is idle ⁽¹⁾	114.2	
	CRYPTO (AES)	Delta current with clock enabled, module is idle	15.5	
	РКА	Delta current with clock enabled, module is idle	66.6	
	TRNG	Delta current with clock enabled, module is idle	21.0	
Sensor Cor	ntroller Engine Consumption			
	Active mode	24 MHz, infinite loop, V _{DDS} = 3.0 V	820	
I _{SCE}	Low-power mode	2 MHz, infinite loop, V _{DDS} = 3.0 V	32	μA

(1) Only one UART running

(2) Only one SPI running

(3) Only one GPTimer running



8.6 Power Consumption - Radio Modes

When measured on the LP-EM-CC1354P10-1 reference design with T_c = 25 °C, V_{DDS} = 3.6 V with DC/DC enabled unless otherwise noted.

Using boost mode (increasing VDDR up to 1.95 V), will increase system current by 15% (does not apply to TX +14 dBm setting where this current is already included).

Relevant I_{core} and I_{peri} currents are included in below numbers.

PARAMETER	TEST CONDITIONS	ТҮР	UNIT
Radio receive current, 868 MHz		5.8	mA
Radio receive current, 2.44 GHz (BLE)	V _{DDS} = 3.0 V	6.9	mA
Radio transmit current	0 dBm output power setting 868 MHz	7.5	mA
Sub-1 GHz PA	+10 dBm output power setting 868 MHz	16.1	mA
Radio transmit current Boost mode, Sub-1 GHz PA	+14 dBm output power setting 868 MHz	25.8	mA
Radio transmit current 2.4 GHz PA (BLE)	0 dBm output power setting, V_{DDS} = 3.0 V	7.1	mA
Radio transmit current 2.4 GHz PA (BLE)	+5 dBm output power setting 2440 MHz, V _{DDS} = 3.0 V	9.6	mA

8.7 Nonvolatile (Flash) Memory Characteristics

Over operating free-air temperature range and $V_{DDS} = 3.0 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Flash sector size			2		kB
Supported flash erase cycles before failure, full bank ^{(1) (5)}		30			k Cycles
Supported flash erase cycles before failure, single sector ⁽²⁾		60			k Cycles
Maximum number of write operations per row before sector $\ensuremath{e}^{(3)}$				83	Write Operations
Flash retention	105 °C	11.4			Years
Flash sector erase current	Average delta current		0.3		mA
Flash sector erase time ⁽⁴⁾	Zero cycles		2.1		ms
	30k cycles			4000	ms
Flash write current	Average delta current, 16 bytes at a time		3.0		mA
Flash write time ⁽⁴⁾	16 bytes at a time		21.4		μs

(1) A full bank erase is counted as a single erase cycle on each sector

(2) Up to 4 customer-designated sectors can be individually erased an additional 30k times beyond the baseline bank limitation of 30k cycles

(3) Each wordline is 2048 bits (or 256 bytes) wide. This limitation corresponds to sequential memory writes of 4 (3.1) bytes minimum per write over a whole wordline. If additional writes to the same wordline are required, a sector erase is required once the maximum number of write operations per row is reached.

(4) This number is dependent on Flash aging and increases over time and erase cycles

(5) Aborting flash during erase or program modes is not a safe operation.

8.8 Thermal Resistance Characteristics

		PAC	KAGE	
	THERMAL METRIC ⁽¹⁾	RGZ (VQFN)	RSK(VQFN)	UNIT
		48 PINS	64 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	23.4	TBD	°C/W ⁽²⁾
R _{0JC(top)}	Junction-to-case (top) thermal resistance	13.3	TBD	°C/W ⁽²⁾
R _{θJB}	Junction-to-board thermal resistance	8.0	TBD	°C/W ⁽²⁾
ΨJT	Junction-to-top characterization parameter	0.1	TBD	°C/W ⁽²⁾
Ψјв	Junction-to-board characterization parameter	7.9	TBD	°C/W ⁽²⁾



8.8 Thermal Resistance Characteristics (continued)

		PAC	KAGE	
	THERMAL METRIC (1)	RGZ (VQFN)	RSK(VQFN)	UNIT
		48 PINS	64 PINS	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	1.7	TBD	°C/W ⁽²⁾

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

(2) °C/W = degrees Celsius per watt.

8.9 RF Frequency Bands

Over operating free-air temperature range (unless otherwise noted).

PARAMETER	MIN	TYP MA	X UNIT
	2360	2360 2500	0
	1076	13	5
	861	105	4 MHz
Frequency bands	431	52	27
	359	43	9
	287	3	1

8.10 861 MHz to 1054 MHz - Receive (RX)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

path. All measurements are perform		MIN TYP	MAN	UNIT
PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
General Parameters				
Digital channel filter programmable receive bandwidth		4	4000	kHz
Data rate step size		1.5		bps
Spurious emissions 25 MHz to 1 GHz	868 MHz	< -57		dBm
Spurious emissions 1 GHz to 13 GHz	Conducted emissions measured according to ETSI EN 300 220	< -47		dBm
Wi-SUN, 50 kbps, ±12.5 kHz deviation, 2-0	GFSK, 78 kHz RX BW, #1a			
Sensitivity	MRFSK, 866.6 MHz, 10% PER, 250 byte payload	-106		dBm
Saturation limit	10% PER, 250 byte payload, 866.6 MHz	10		dBm
Selectivity, +100 kHz		33		dB
Selectivity, -100 kHz	10% PER, 250 byte payload, 866.6 MHz. Wanted signal 3 dB	31		dB
Selectivity, +200 kHz	above sensitivity level.	38		dB
Selectivity, -200 kHz		37		dB
RSSI dynamic range	Starting from the sensitivity limit	93		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Wi-SUN, 50 kbps, ±25 kHz deviation, 2-GF	SK, 100 kHz RX BW, #1b			
Sensitivity	MRFSK, 918.2 MHz, 10% PER, 250 byte payload	-106		dBm
Saturation limit	10% PER, 250 byte payload, 918.2 MHz	10		dBm
Selectivity, +200 kHz		37		dB
Selectivity, -200 kHz	10% PER 250 byte payload 918 2 MHz Wanted signal 3 dB	35		dB
Selectivity, +400 kHz	above sensitivity level.	42		dB
Selectivity, -400 kHz	-	41		dB
RSSI dynamic range	Starting from the sensitivity limit	95		dB
RSSI accuracy		±3		dB
Wi-SUN, 100 kbps, ±25 kHz deviation, 2-G				
Sensitivity		-103		dBm
Saturation limit		10		dBm
Selectivity, +200 kHz		40		dB
Selectivity, -200 kHz	10% DEP. 250 byte poyload 266 6 MHz. Wested signal 2 dP	38		dB
Selectivity, +400 kHz	4 868 MHz Conducted emissions measured according to ETSI EN 300 220 SK, 78 kHz RX BW, #1a MRFSK, 866.6 MHz, 10% PER, 250 byte payload 10% PER, 250 byte payload, 866.6 MHz 10% PER, 250 byte payload, 866.6 MHz. Starting from the sensitivity limit Starting from the sensitivity limit MRFSK, 918.2 MHz, 10% PER, 250 byte payload 10% PER, 250 byte payload, 918.2 MHz. WRFSK, 866.6 MHz, 10% PER, 250 byte payload 10% PER, 250 byte payload, 866.6 MHz. WRFSK, 866.6 MHz, 10% PER, 250 byte payload 10% PER, 250 byte payload, 866.6 MHz. Wanted signal 3 dB above sensitivity limit Starting from the sensitivity limit Starting fr	46		dB
Selectivity, -400 kHz	-	44		dB
RSSI dynamic range	Starting from the sensitivity limit	95		dB
RSSI accuracy		±3		dB
Wi-SUN, 100 kbps, ±50 kHz deviation, 2-G		10		
Sensitivity		-102		dBm
Saturation limit		102		dBm
		42		dB
Selectivity, +400 kHz	-			
Selectivity, -400 kHz		39		dB
Selectivity, +800 kHz		52		dB
Selectivity, -800 kHz	Ctarting from the consitiuity limit	46		dB
RSSI dynamic range		91		dB
RSSI accuracy		±3		dB
Wi-SUN, 150 kbps, ±37.5 kHz deviation, 2				
Sensitivity		-99		dBm
Saturation limit	10% PER, 250 byte payload, 918.4 MHz	10		dBm



When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Selectivity, +400 kHz		41		dB
Selectivity, -400 kHz	10% PER, 250 byte payload, 918.4 MHz. Wanted signal 3 dB	39		dB
Selectivity, +800 kHz	above sensitivity level.	50		dB
Selectivity, -800 kHz		46		dB
RSSI dynamic range	Starting from the sensitivity limit	86		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Wi-SUN, 200 kbps, ±50 kHz deviatio	n, 2-GFSK, 335 kHz RX BW, #4a			
Sensitivity	MRFSK, 918.4 MHz, 10% PER, 250 byte payload	-99		dBm
Saturation limit	10% PER, 250 byte payload, 918.4 MHz	10		dBm
Selectivity, +400 kHz		42		dB
Selectivity, -400 kHz	10% PER, 250 byte payload, 918.4 MHz. Wanted signal 3 dB	40		dB
Selectivity, +800 kHz	above sensitivity level.	51		dB
Selectivity, -800 kHz		47		dB
RSSI dynamic range	Starting from the sensitivity limit	91		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Wi-SUN, 200 kbps, ±100 kHz deviati	on, 2-GFSK, 416 kHz RX BW, #4b			
Sensitivity	MRFSK, 920.8 MHz, 10% PER, 250 byte payload	-98		dBm
Saturation limit	10% PER, 250 byte payload, 920.8 MHz	10		dBm
Selectivity, +600 kHz		46		dB
Selectivity, -600 kHz	10% PER, 250 byte payload, 920.8 MHz. Wanted signal 3 dB	43		dB
Selectivity, +1200 kHz	above sensitivity level, modulated blocker.	54		dB
Selectivity, -1200 kHz		51		dB
RSSI dynamic range	Starting from the sensitivity limit	86		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Wi-SUN, 300 kbps, ±75 kHz deviatio	n, 2-GFSK, 496 kHz RX BW, #5			
Sensitivity	MRFSK, 917.6 MHz, 10% PER, 250 byte payload	-97		dBm
Saturation limit	10% PER, 250 byte payload, 917.6 MHz	10		dBm
Selectivity, +600 kHz		42		dB
Selectivity, -600 kHz	10% PER, 250 byte payload, 917.6 MHz. Wanted signal 3 dB	37		dB
Selectivity, +1200 kHz	above sensitivity level.	51		dB
Selectivity, -1200 kHz		40		dB
RSSI dynamic range	Starting from the sensitivity limit	86		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
802.15.4-2020, 10 kbps, 2-FSK, 26 k	Hz RX BW, Mode #1a			
Sensitivity	FSK, 915.0 MHz, 20 byte PSDU < 10% PER	-113		dBm
Sensitivity	FSK, 868.3 MHz, 20 byte PSDU < 10% PER	-113		dBm
Saturation limit	PSDU length 20 octets; PER < 10%, 868.3 MHz	10		dBm

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted

PARAMETER	rmed conducted. TEST CONDITIONS	MIN TYP M	AX UNIT
Selectivity, +50 kHz		36	dB
Selectivity, -50 kHz	—	36	dB
Selectivity, +100 kHz	—	40	dB
Selectivity, -100 kHz	—	39	dB
Selectivity, +200 kHz	—	44	dB
Selectivity, -200 kHz	—	37	dB
Blocking, +1 MHz	—	60	dB
Blocking, -1 MHz	PSDU length 20 octets; PER < 10%, 868.3 MHz	59	dB
Blocking, +2 MHz	—	64	dB
Blocking, -2 MHz	—	64	dB
Blocking, +5 MHz	—	75	dB
Blocking, -5 MHz	—	74	dB
Blocking, +10 MHz	—	79	dB
Blocking, -10 MHz		79	dB
Selectivity, +50 kHz		35	dB
Selectivity, -50 kHz	—	35	dB
Selectivity, +100 kHz	—	39	dB
Selectivity, -100 kHz	—	38	dB
Selectivity, +200 kHz	—	44	dB
Selectivity, -200 kHz	according to ETSI EN 300 220 V3.1.1 (usable sensitivity -97 dBm). Limit is Cat 1.5 requirement. PSDU length 20 octets; PER < 10%, 868.3 MHz	44	dB
Blocking, +1 MHz		58	dB
Blocking, -1 MHz		58	dB
Blocking, +2 MHz		62	dB
Blocking, -2 MHz		63	dB
Blocking, +5 MHz		74	dB
Blocking, -5 MHz		74	dB
Blocking, +10 MHz		73	dB
Blocking, -10 MHz		78	dB
Blocking + 5% Fc. (45.75 MHz)	10% PER 20 byte payload 866 6 MHz 802 15 4g mandatory	-15	dBm
Blocking - 5% Fc. (-45.75 MHz)	mode, wanted signal -94 dBm. 3 dB above usable sensitivity limit	-15	dBm
Image rejection (image compensation enabled)	according to ETSI EN 300 220 V3.1.1 (usable sensitivity -97 dBm). Limit is Cat 1.5 requirement.	39	dB
Image rejection (image compensation enabled)	PSDU length 20 octets; PER < 10%, 868.3 MHz	39	dB
Image rejection (image compensation enabled)	-40 to 125°C, 10% PER, 250 byte payload, 866.6 MHz	39	dB
RSSI dynamic range	Starting from the sensitivity limit	100	dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3	dB
Frequency error tolerance (ppm)	10% PER, 20 byte payload, measured at 10 dB above sensitivity level. Negative offset	-12	ppm
Frequency error tolerance (ppm)	10% PER, 20 byte payload, measured at 10 dB above sensitivity level. Positive offset	12	ppm
Symbol rate error tolerance (ppm)	10% PER, 20 byte payload, measured at 10 dB above sensitivity level. Negative offset	-1000	ppm
Symbol rate error tolerance (ppm)	1% BER, measured at 10 dB above sensitivity level	1000	ppm



When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Sensitivity	FSK, 20 kbps, ±10 kHz deviation, 2-GFSK, 915.0 MHz, 52 kHz RX BW, 20 byte PSDU < 10% PER	-110		dBm
Sensitivity	FSK, 20 kbps, ±10 kHz deviation, 2-GFSK, 868.3 MHz, 52 kHz RX BW, 20 byte PSDU < 10% PER	-110		dBm
Saturation limit	20 byte PSDU < 10% PER, 868.3 MHz	10		dBm
Selectivity, +100 kHz		38		dB
Selectivity, -100 kHz		36		dB
Selectivity, +200 kHz		44		dB
Selectivity, -200 kHz		42		dB
Selectivity, +400 kHz		49		dB
Selectivity, -400 kHz		44		dB
Blocking, +1 MHz		58		dB
Blocking, -1 MHz		54		dB
Blocking, -2 MHz		61		dB
Blocking, +2 MHz		61		dB
Blocking, -5 MHz		70		dB
Blocking, +5 MHz		70		dB
Blocking, -10 MHz		75		dB
Blocking, +10 MHz		76		dB
Selectivity, +100 kHz		36		dB
Selectivity, -100 kHz		34		dB
Selectivity, +200 kHz		42		dB
Selectivity, -200 kHz	-	41		dB
Selectivity, +400 kHz		47		dB
Selectivity, -400 kHz		46		dB
Blocking, +1 MHz	20 byte PSDU < 10% PER, 868.3 MHz. Wanted signal 3 dB	56		dB
Blocking, -1 MHz	above sensitivity level.	55		dB
Blocking, +2 MHz		61		dB
Blocking, -2 MHz		61		dB
Blocking, +5 MHz		71		dB
Blocking, -5 MHz		70		dB
Blocking, +10 MHz		75		dB
Blocking, -10 MHz		75		dB
Blocking + 5% Fc. (45.75 MHz)	20 byte PSDU < 10% PER, 866.6 MHz, wanted signal -94 dBm.	-13		dBm
Blocking - 5% Fc. (-45.75 MHz)	3 dB above usable sensitivity limit according to ETSI EN 300 220 V3.1.1 (usable sensitivity -97 dBm). Limit is Cat 1.5 requirement.	-13		dBm
Image rejection (image compensation enabled)	20 byte PSDU < 10% PER, 866.6 MHz. Wanted signal 3 dB above sensitivity limit.	39		dB
Image rejection (image compensation enabled)	20 byte PSDU < 10% PER, 866.6 MHz ⁽¹⁾	39		dB
Image rejection (image compensation enabled)	-40 to 125°C, 10% PER, 250 byte payload, 866.6 MHz	39		dB
RSSI dynamic range	Starting from the sensitivity limit	100		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Frequency error tolerance (ppm)	20 byte PSDU < 10% PER, measured at 10 dB above sensitivity level. Negative offset	-24		ppm
Frequency error tolerance (ppm)	20 byte PSDU < 10% PER, measured at 10 dB above sensitivity level. Positive offset	24		ppm

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Symbol rate error tolerance (ppm)	20 byte PSDU < 10% PER, measured at 10 dB above sensitivity level.	-1000		ppm
	Negative offset 20 byte PSDU < 10% PER, measured at 10 dB above sensitivity			
Symbol rate error tolerance (ppm)	level.	1000		ppm
	Negative offset			
802.15.4, 200 kbps, ±50 kHz deviation,				
Sensitivity	BER = 10 ⁻² , 868 MHz	-103		dBm
Sensitivity	BER = 10 ⁻² , 915 MHz	-103		dBm
Selectivity, +400 kHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	45		dB
Selectivity, -400 kHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	45		dB
Selectivity, +800 kHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	52		dB
Selectivity, -800 kHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	47		dB
Blocking, +2 MHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	59		dB
Blocking, -2 MHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	56		dB
Blocking, +10 MHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	71		dB
Blocking, -10 MHz	BER = 10 ⁻² , 915 MHz. Wanted signal 3 dB above sensitivity limit.	70		dB
802.15.4, 500 kbps, ±190 kHz deviatior	n, 2-GFSK, 622 kHz RX BW		1	
Sensitivity 500 kbps	915 MHz, 1% PER, 127 byte payload	-95		dBm
Selectivity, ±1 MHz	915 MHz, 1% PER, 127 byte payload. Wanted signal at -88 dBm	34		dB
Selectivity, ±2 MHz	915 MHz, 1% PER, 127 byte payload. Wanted signal at -88 dBm	46		dB
Co-channel rejection	915 MHz, 1% PER, 127 byte payload. Wanted signal at -71 dBm	-8		dB
	(20 ksps), ±5 kHz Deviation, 2-GFSK, 34 kHz RX Bandwidth, FEC = 1:	2, DSSS = 1:4/1:2		
Sensitivity	2.5 kbps, BER = 10 ⁻² , 868 MHz	-121		dBm
Sensitivity	2.5 kbps, BER = 10 ⁻² , 915 MHz	-121		dBm
Sensitivity	5 kbps, BER = 10 ⁻² , 868 MHz	-119		dBm
Sensitivity	5 kbps, BER = 10 ⁻² , 915 MHz	-119		dBm
Saturation limit	2.5 kbps, BER = 10 ⁻² , 868 MHz	10		dBm
Selectivity, +100 kHz	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	49		dB
Selectivity, -100 kHz	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	49		dB
Selectivity, +200 kHz	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	52		dB
Selectivity, -200 kHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	48		dB
Selectivity, +300 kHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	54		dB
Selectivity, -300 kHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	48		dB
Blocking, +1 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	65		dB
Blocking, -1 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	60		dB
Blocking, +2 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	70		dB
Blocking, -2 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	68		dB
<u> </u>	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	78		dB
Blocking, +5 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾			
Blocking, -5 MHz	2.5 kbps, BER = 10^{-2} , 868 MHz ⁽¹⁾	77		dB
Blocking, +10 MHz		87		dB
Blocking, -10 MHz	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	92		dB
mage rejection (image compensation enabled)	2.5 kbps, BER = 10 ⁻² , 868 MHz ⁽¹⁾	47		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Frequency error tolerance (ppm)	2.5 kbps, 20 kbaud, DSSS=4, ½ K=7 FEC. measured at -110 dBm.	-24/26		ppm
Symbolrate error tolerance (ppm)	2.5 kbps, 20 kbaud, DSSS=4, ½ K=7 FEC. measured at -110 dBm. Refered to 20 kbaud chip rate.	-90/70		ppm



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8.10 861 MHz to 1054 MHz - Receive (RX) (continued)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25 \text{ °C}$, $V_{DDS} = 3.0 \text{ V}$ with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Narrowband, 9.6 kbps ±2.4 kHz deviatio	n, 2-GFSK, 868 MHz, 17.1 kHz RX BW			
Sensitivity	1% BER	-117		dBm
Adjacent Channel Rejection	1% BER. Wanted signal 3 dB above usable sensitivity limit (usable sensitivity -104.6 dBm). Interferer ±20 kHz	42		dB
Alternate Channel Rejection	1% BER. Wanted signal 3 dB above usable sensitivity limit (usable sensitivity -104.6 dBm). Interferer ±40 kHz	42		dB
Blocking, ±1 MHz	1% BER. Wanted signal 3 dB above usable sensitivity limit (usable sensitivity -104.6 dBm).	66		dB
Blocking, ±2 MHz	1% BER. Wanted signal 3 dB above usable sensitivity limit (usable sensitivity -104.6 dBm).	71		dB
Blocking, ±10 MHz	1% BER. Wanted signal 3 dB above usable sensitivity limit (usable sensitivity -104.6 dBm).	85		dB
802.15.4, 50 kbps, ±25 kHz Deviation, 2-	GFSK, 100 kHz RX BW (Legacy)			
Sensitivity	BER = 10 ⁻² , 868 MHz	-110		dBm
Sensitivity	BER = 10 ⁻² , 915 MHz	-110		dBm
Saturation limit	BER = 10 ⁻² , 868 MHz	10		dBm
Selectivity, +200 kHz		44		dB
Selectivity, -200 kHz		44		dB
Selectivity, +400 kHz		54		dB
Selectivity, -400 kHz		44		dB
Blocking, +1 MHz		57		dB
Blocking, -1 MHz	—	57		dB
Blocking, +2 MHz	BER = 10 ⁻² , 868 MHz ⁽¹⁾	61		dB
Blocking, -2 MHz		61		dB
Blocking, +5 MHz		67		dB
Blocking, -5 MHz		67		dB
Blocking, +10 MHz		76		dB
Blocking, -10 MHz		76		dB
Selectivity, +200 kHz		45		dB
Selectivity, -200 kHz		45		dB
Selectivity, +400 kHz	-	51		dB
	-	45		dB
Selectivity, -400 kHz				
Blocking, +1 MHz		61		dB
Blocking, -1 MHz	BER = 10 ⁻² , 868 MHz. Wanted signal 3 dB above sensitivity limit.	61		dB
Blocking, +2 MHz		63		dB
Blocking, -2 MHz		63		dB
Blocking, +5 MHz		67		dB
Blocking, -5 MHz		67		dB
Blocking, +10 MHz		73		dB
Blocking, -10 MHz		73		dB
Blocking + 5% Fc. (43.42 MHz)	BER = 10 ⁻² , 868 MHz 802.15.4g mandatory mode, wanted signal -94 dBm. 3 dB above	-15		dBm
Blocking - 5% Fc. (-43.42 MHz)	usable sensitivity -97 dBm). Limit is Cat 1.5 requirement.	-15		dBm
Image rejection (image compensation enabled)	BER = 10 ⁻² , 868 MHz. Wanted signal 3 dB above sensitivity limit.	39		dB
Image rejection (image compensation enabled)	BER = 10 ⁻² , 868 MHz ⁽¹⁾	39		dB
Image rejection (image compensation enabled)	-40 to 125°C. BER = 10 ⁻² , 868 MHz	41		dB

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
RSSI dynamic range	Starting from the sensitivity limit	95		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Frequency error tolerance (ppm)	1% BER, measured at -100 dBm (10 dB above sensitivity level). Negative offset	-30		ppm
Frequency error tolerance (ppm)	1% BER, measured at -100 dBm (10 dB above sensitivity level). Positive offset	25		ppm
Symbol rate error tolerance (ppm)	1% BER, measured at-100 dBm (10 dB above sensitivity level). Negative offset	-2000		ppm
Symbol rate error tolerance (ppm)	1% BER, measured at-100 dBm (10 dB above sensitivity level) Positive offset	2000		ppm
802.15.4, 100 kbps, ±25 kHz deviation	n, 2-GFSK, 137 kHz RX BW			
Sensitivity 100 kbps	868 MHz, 1% PER, 127 byte payload	-103		dBm
Selectivity, ±200 kHz		38		dB
Selectivity, ±400 kHz	868 MHz, 1% PER, 127 byte payload. Wanted signal at -96 dBm	44		dB
Co-channel rejection	868 MHz, 1% PER, 127 byte payload. Wanted signal at -79 dBm	-9		dB
Generic OOK (16.384 kbps, OOK w / I	Manchester encoding, 100 kHz RX BW)			
Sensitivity	OOK, 915.0 MHz, 1% BER	-114		dBm
Sensitivity	OOK, 868.8 MHz, 1% BER	-113		dBm
Saturation limit	868.3 MHz	0		dBm
Selectivity, +200 kHz		52		dB
Selectivity, -200 kHz		48		dB
Selectivity, +400 kHz	—	68		dB
Selectivity, -400 kHz	—	64		dB
Blocking, +1 MHz	—	64		dB
Blocking, -1 MHz	——	59		dB
Blocking, +2 MHz		64		dB
Blocking, -2 MHz		59		dB
Blocking, +5 MHz		72		dB
Blocking, -5 MHz		73		dB
Blocking, +10 MHz		64		dB
Blocking, -10 MHz		58		dB
Selectivity, +200 kHz		52		dB
Selectivity, -200 kHz		47		dB
Selectivity, +400 kHz		42		dB
Selectivity, -400 kHz		42		dB
Blocking, +1 MHz		68		dB
Blocking, -1 MHz		64		dB
-	868.3 MHz. Wanted signal 3 dB above sensitivity level.			
Blocking, +2 MHz		68		dB dB
Blocking, -2 MHz		64		
Blocking, +5 MHz		74		dB
Blocking, -5 MHz		73		dB
Blocking, +10 MHz		68		dB
Blocking, -10 MHz		64		dB
RSSI dynamic range	Starting from the sensitivity limit	95		dB
RSSI accuracy	Starting from the sensitivity limit across the given dynamic range	±3		dB
Frequency error tolerance (ppm)	Measured at 10 dB above sensitivity level. Negative offset	-40		ppm
Frequency error tolerance (ppm)	Measured at 10 dB above sensitivity level. Positive offset	40		ppm



When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Symbol rate error tolerance (ppm)	Measured at 10 dB above sensitivity level. Negative offset		-2000		ppm
Symbol rate error tolerance (ppm)	Measured at 10 dB above sensitivity level Positive offset		2000		ppm

(1) Wanted signal 3 dB above usable sensitivity limit according to ETSI EN 300 220 v. 3.1.1.

8.11 861 MHz to 1054 MHz - Transmit (TX)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted. ⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN TYP M	IAX UNIT
General parameters				
Max output power, boost m	ode Sub-1 GHz PA ⁽²⁾	VDDR = 1.95 V Minimum supply voltage (VDDS) for boost mode is 2.1 V 868 MHz and 915 MHz	14	dBm
Max output power, Sub-1 GHz PA ⁽²⁾		868 MHz and 915 MHz	12	dBm
Output power programmab	le range Sub-1 GHz PA	868 MHz and 915 MHz, 1dB step size.	34	dB
Output power variation ove Sub-1 GHz PA	r temperature	+10 dBm setting Over recommended temperature operating range	±2	dB
Output power variation ove PA	r temperature Boost mode, Sub-1 GHz	+14 dBm setting Over recommended temperature operating range	±1.5	dB
Spurious emissions and	harmonics			
Spurious emissions 30 MHz to 1 GHz		+14 dBm setting ETSI restricted bands	< -54	dBm
(excluding harmonics) Sub-1 GHz PA, 868 MHz		+14 dBm setting ETSI outside restricted bands	< -36	dBm
(3)	1 GHz to 12.75 GHz (outside ETSI restricted bands)	+14 dBm setting measured in 1 MHz bandwidth (ETSI)	< -30	dBm
	30 MHz to 88 MHz (within FCC restricted bands)	+14 dBm setting	< -56	dBm
	88 MHz to 216 MHz (within FCC restricted bands)	+14 dBm setting	< -52	dBm
Spurious emissions out- of-band Sub-1 GHz PA, 915 MHz	216 MHz to 960 MHz (within FCC restricted bands)	+14 dBm setting	< -50	dBm
(3)	960 MHz to 2390 MHz and above 2483.5 MHz (within FCC restricted band)	+14 dBm setting	<-42	dBm
	1 GHz to 12.75 GHz (outside FCC restricted bands)	+14 dBm setting	< -40	dBm
	Below 710 MHz (ARIB T-108)	+14 dBm setting	< -36	dBm
	710 MHz to 900 MHz (ARIB T-108)	+14 dBm setting	< -55	dBm
Spurious emissions out- of-band	900 MHz to 915 MHz (ARIB T-108)	+14 dBm setting	< -55	dBm
Sub-1 GHz PA, 920.6/928 MHz ⁽³⁾	930 MHz to 1000 MHz (ARIB T-108)	+14 dBm setting	< -55	dBm
	1000 MHz to 1215 MHz (ARIB T-108)	+14 dBm setting	< -45	dBm
	Above 1215 MHz (ARIB T-108)	+14 dBm setting	< -30	dBm
	Second harmonic	+14 dBm setting, 868 MHz	< -30	dBm
		+14 dBm setting, 915 MHz	< -30	
	Third harmonic	+14 dBm setting, 868 MHz	< -30	dBm
Harmonics		+14 dBm setting, 915 MHz	< -42	
Sub-1 GHz PA	Fourth harmonic	+14 dBm setting, 868 MHz	< -30	dBm
		+14 dBm setting, 915 MHz	< -30	
	Fifth harmonic	+14 dBm setting, 868 MHz	< -30	dBm
		+14 dBm setting, 915 MHz	< -42	

(1) Some combinations of frequency, data rate and modulation format requires use of external crystal load capacitors for regulatory compliance. More details can be found in the device errata.



- (2) Output power is dependent on RF match. For dual-band devices in the CC13X4 platform, output power might be slightly reduced depending on RF layout trade-offs.
- (3) Suitable for systems targeting compliance with EN 300 220, EN 303 131, EN 303 204, FCC CFR47 Part 15, ARIB STD-T108.

8.12 861 MHz to 1054 MHz - PLL Phase Noise Wideband Mode

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	±10 kHz offset		-74		dBc/Hz
	±100 kHz offset		-97		dBc/Hz
	±200 kHz offset		-107		dBc/Hz
Phase noise in the 868- and 915-MHz bands 20 kHz PLL loop bandwidth	±400 kHz offset		-113		dBc/Hz
	±1000 kHz offset		-120		dBc/Hz
	±2000 kHz offset		-127		dBc/Hz
	±10000 kHz offset		-141		dBc/Hz

8.13 861 MHz to 1054 MHz - PLL Phase Noise Narrowband Mode

When measured on the LP-EM-CC1354P10-1 reference design with T_c = 25 °C, V_{DDS} = 3.0 V.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	±10 kHz offset		-96		dBc/Hz
	±100 kHz offset		-95		dBc/Hz
	±200 kHz offset		-94		dBc/Hz
Phase noise in the 868- and 915-MHz bands 150 kHz PLL loop bandwith	±400 kHz offset		-104		dBc/Hz
	±1000 kHz offset		-121		dBc/Hz
	±2000 kHz offset		-130		dBc/Hz
	±10000 kHz offset		-140		dBc/Hz



8.14 Bluetooth Low Energy - Receive (RX)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
125 kbps (LE Coded)				
Receiver sensitivity	Differential mode. BER = 10 ⁻³	-104		dBm
Receiver saturation	Differential mode. BER = 10 ⁻³	>5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-300 / 300)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-320 / 240)		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)	> (–100 / 125)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -79 dBm, modulated interferer in channel, BER = 10^{-3}	-1.5		dB
Selectivity, ±1 MHz ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	8 / 4.5 ⁽²⁾		dB
Selectivity, ±2 MHz ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at ± 2 MHz, BER = 10^{-3}	44 / 39 ⁽²⁾		dB
Selectivity, ±3 MHz ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at ± 3 MHz, BER = 10^{-3}	43 / 43 ⁽²⁾		dB
Selectivity, ±4 MHz ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	44 / 43 ⁽²⁾		dB
Selectivity, ±6 MHz ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at $\ge \pm 6$ MHz, BER = 10^{-3}	48 / 43 ⁽²⁾		dB
Selectivity, ±7 MHz	Wanted signal at –79 dBm, modulated interferer at $\ge \pm 7$ MHz, BER = 10^{-3}	51 / 45 ⁽²⁾		dB
Selectivity, Image frequency ⁽¹⁾	Wanted signal at –79 dBm, modulated interferer at image frequency, BER = 10^{-3}	39		dB
Selectivity, Image frequency ± 1 MHz ⁽¹⁾	Note that Image frequency + 1 MHz is the Co- channel – 1 MHz. Wanted signal at –79 dBm, modulated interferer at ±1 MHz from image frequency, BER = 10^{-3}	4.5 / 44 ⁽²⁾		dB
RSSI Range		89		dB
RSSI Accuracy (+/-)		±4		dB
500 kbps (LE Coded)		L		
Receiver sensitivity	Differential mode. BER = 10 ⁻³	-100		dBm
Receiver saturation	Differential mode. BER = 10 ⁻³	> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-300 / 300)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (–450 / 450)		ppm
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (255-byte packets)	> (–175 / 175)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -72 dBm, modulated interferer in channel, BER = 10^{-3}	-3.5		dB
Selectivity, ±1 MHz ⁽¹⁾	Wanted signal at –72 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	8 / 4 ⁽²⁾		dB
Selectivity, ±2 MHz ⁽¹⁾	Wanted signal at –72 dBm, modulated interferer at ±2 MHz, BER = 10^{-3}	41 / 37 ⁽²⁾		dB
Selectivity, ±3 MHz ⁽¹⁾	Wanted signal at –72 dBm, modulated interferer at ± 3 MHz, BER = 10^{-3}	44 / 41 ⁽²⁾		dB
Selectivity, ±4 MHz ⁽¹⁾	Wanted signal at –72 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	44 / 43 ⁽²⁾		dB
Selectivity, ±6 MHz ⁽¹⁾	Wanted signal at –72 dBm, modulated interferer at $\ge \pm 6$ MHz, BER = 10^{-3}	46 / 43 ⁽²⁾		dB
Selectivity, ±7 MHz	Wanted signal at –72 dBm, modulated interferer at $\ge \pm 7$ MHz, BER = 10^{-3}	49 / 45 ⁽²⁾		dB



8.14 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Selectivity, Image frequency ⁽¹⁾	Wanted signal at -72 dBm, modulated interferer at image frequency, BER = 10^{-3}	37		dB
Selectivity, Image frequency ± 1 MHz ⁽¹⁾	Note that Image frequency + 1 MHz is the Co- channel – 1 MHz. Wanted signal at –72 dBm, modulated interferer at \pm 1 MHz from image frequency, BER = 10^{-3}	4 / 46 ⁽²⁾		dB
RSSI Range		85		dB
RSSI Accuracy (+/-)		±4		dB
1 Mbps (LE 1M)				
Receiver sensitivity	Differential mode. BER = 10 ⁻³	-97		dBm
Receiver saturation	Differential mode. BER = 10 ⁻³	> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-350 / 350)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-750 / 750)		ppm
Co-channel rejection ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer in channel, BER = 10^{-3}	-6		dB
Selectivity, ±1 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ±1 MHz, BER = 10^{-3}	7 / 4 ⁽²⁾		dB
Selectivity, ±2 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ±2 MHz,BER = 10^{-3}	40 / 33 ⁽²⁾		dB
Selectivity, ±3 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ±3 MHz, BER = 10^{-3}	36 / 41 ⁽²⁾		dB
Selectivity, ±4 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	36 / 45 ⁽²⁾		dB
Selectivity, ±5 MHz or more ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at $\ge\pm5$ MHz, BER = 10^{-3}	40		dB
Selectivity, image frequency ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at image frequency, BER = 10^{-3}	33		dB
Selectivity, image frequency ±1 MHz ⁽¹⁾	Note that Image frequency + 1 MHz is the Co- channel – 1 MHz. Wanted signal at –67 dBm, modulated interferer at \pm 1 MHz from image frequency, BER = 10 ⁻³	4 / 41 ⁽²⁾		dB
Out-of-band blocking ⁽³⁾	30 MHz to 2000 MHz	-10		dBm
Out-of-band blocking	2003 MHz to 2399 MHz	-18		dBm
Out-of-band blocking	2484 MHz to 2997 MHz	-12		dBm
Out-of-band blocking	3000 MHz to 12.75 GHz	-2		dBm
Intermodulation	Wanted signal at 2402 MHz, –64 dBm. Two interferers at 2405 and 2408 MHz respectively, at the given power level	-42		dBm
Spurious emissions, 30 to 1000 MHz ⁽⁴⁾	Measurement in a 50 Ω single-ended load.	< -59		dBm
Spurious emissions, 1 to 12.75 GHz ⁽⁴⁾	Measurement in a 50 Ω single-ended load.	< -47		dBm
RSSI dynamic range		70		dB
RSSI accuracy		±4	_	dB
2 Mbps (LE 2M)	· · ·			
Receiver sensitivity	Differential mode. Measured at SMA connector, BER = 10^{-3}	-92		dBm
Receiver saturation	Differential mode. Measured at SMA connector, BER = 10^{-3}	> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> (-500 / 500)		kHz
Data rate error tolerance	Difference between incoming data rate and the internally generated data rate (37-byte packets)	> (-700 / 750)	_	ppm

8.14 Bluetooth Low Energy - Receive (RX) (continued)

When measured on the LP-EM-CC1354P10-1 reference design with T_c = 25 °C, V_{DDS} = 3.0 V, f_{RF}= 2440 MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
Co-channel rejection ⁽¹⁾	Wanted signal at -67 dBm, modulated interferer in channel,BER = 10^{-3}		-7	dB
Selectivity, ±2 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ± 2 MHz, Image frequency is at –2 MHz, BER = 10^{-3}	8 /	4 ⁽²⁾	dB
Selectivity, ±4 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ±4 MHz, BER = 10^{-3}	35/3	32(2)	dB
Selectivity, ±6 MHz ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at ± 6 MHz, BER = 10^{-3}	37/3	34(2)	dB
Selectivity, image frequency ⁽¹⁾	Wanted signal at –67 dBm, modulated interferer at image frequency, BER = 10^{-3}		4	dB
Selectivity, image frequency ±2 MHz ⁽¹⁾	Note that Image frequency + 2 MHz is the Co-channel. Wanted signal at –67 dBm, modulated interferer at ± 2 MHz from image frequency, BER = 10^{-3}	-7/3	3 6 ⁽²⁾	dB
Out-of-band blocking ⁽³⁾	30 MHz to 2000 MHz		–16	dBm
Out-of-band blocking	2003 MHz to 2399 MHz		-21	dBm
Out-of-band blocking	2484 MHz to 2997 MHz		–15	dBm
Out-of-band blocking	3000 MHz to 12.75 GHz		-20	dBm
Intermodulation	Wanted signal at 2402 MHz, –64 dBm. Two interferers at 2408 and 2414 MHz respectively, at the given power level		-37	dBm
RSSI Range			64	dB
RSSI Accuracy (+/-)			±4	dB

Numbers given as I/C dB (1)

X / Y, where X is +N MHz and Y is -N MHz (2)

Excluding one exception at F_{wanted} / 2, per Bluetooth Specification

(3) (4) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan)



8.15 Bluetooth Low Energy - Transmit (TX)

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER		TEST CONDITIONS		MAX	UNIT
General Parameters					
Max output power, 2.4 GHz PA	Differential mode, delivered to a sing	Differential mode, delivered to a single-ended 50 Ω load through a balun			dBm
Output power programmable range, 2.4 GHz PA	Differential mode, delivered to a single-ended 50 Ω load through a balun		26		dB
Spurious emissions a	nd harmonics				
	f < 1 GHz, outside restricted bands		< -36		dBm
Spurious emissions,	f < 1 GHz, restricted bands ETSI		<54		dBm
2.4 GHz PA	f < 1 GHz, restricted bands FCC		<55		dBm
	f > 1 GHz, including harmonics	- +5 dBm setting 	< -42		dBm
Harmonics, 2.4 GHz PA	Second harmonic		< -42		dBm
	Third harmonic		< -42		dBm



8.16 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - RX

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN TYP MA	X UNIT
General Parameters	· · · · · ·		
Receiver sensitivity	Coherent mode PER = 1%	-105	dBm
Receiver saturation	PER = 1%	> -10	dBm
Adjacent channel rejection	Wanted signal at –82 dBm, modulated interferer at \pm 5 MHz, PER = 1%	36	dB
Alternate channel rejection	Wanted signal at –82 dBm, modulated interferer at \pm 10 MHz, PER = 1%	55	dB
Channel rejection, ±15 MHz or more	Wanted signal at –82 dBm, undesired signal is IEEE 802.15.4 modulated channel, stepped through all channels 2405 to 2480 MHz, PER = 1%	59	dB
Blocking and desensitization, 5 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	57	dB
Blocking and desensitization, 10 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	62	dB
Blocking and desensitization, 20 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	62	dB
Blocking and desensitization, 50 MHz from upper band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	65	dB
Blocking and desensitization, –5 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	60	dB
Blocking and desensitization, –10 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	60	dB
Blocking and desensitization, –20 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	60	dB
Blocking and desensitization, –50 MHz from lower band edge	Wanted signal at –97 dBm (3 dB above the sensitivity level), CW jammer, PER = 1%	62	dB
Spurious emissions, 30 MHz to 1000 MHz	Measurement in a 50 Ω single-ended load	-66	dBm
Spurious emissions, 1 GHz to 12.75 GHz	Measurement in a 50 Ω single-ended load	-53	dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> 100	ppm
Symbol rate error tolerance	Difference between incoming symbol rate and the internally generated symbol rate	> 800	ppm
RSSI dynamic range		95	dB
RSSI accuracy		±4	dB



8.17 Zigbee and Thread - IEEE 802.15.4-2006 2.4 GHz (OQPSK DSSS1:8, 250 kbps) - TX

When measured on the LP-EM-CC1354P10-1 reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, $f_{RF} = 2440$ MHz with DC/DC enabled unless otherwise noted. All measurements are performed at the antenna input with a combined RX and TX path. All measurements are performed conducted.

PARAMETER		TEST CONDITIONS	MIN TYP N		
General Parameters					
Max output power, 2.4 GHz PA	Differential mode, delivered to a si	fferential mode, delivered to a single-ended 50 Ω load through a balun		dBm	
Output power programmable range, 2.4 GHz PA	Differential mode, delivered to a si	fferential mode, delivered to a single-ended 50 Ω load through a balun			
Spurious emissions and	harmonics			1	
	f < 1 GHz, outside restricted bands	+5 dBm setting	< -36	dBm	
Spurious emissions,	f < 1 GHz, restricted bands ETSI		< -47	dBm	
2.4 GHz PA	f < 1 GHz, restricted bands FCC		< -55	dBm	
	f > 1 GHz, including harmonics		< -42	dBm	
Harmonics,	Second harmonic		< -42	dBm	
2.4 GHz PA	Third harmonic		< -42	dBm	
IEEE 802.15.4-2006 2.4 (GHz (OQPSK DSSS1:8, 250 kbps)				
Error vector magnitude, 2.4-GHz PA	+5 dBm setting		2	%	

8.18 Timing and Switching Characteristics

8.18.1 Reset Timing

PARAMETER	MIN	TYP	MAX	UNIT
RESET_N low duration	1			μs

8.18.2 Wakeup Timing

Measured over operating free-air temperature with V_{DDS} = 3.0 V (unless otherwise noted). The times listed here do not include software overhead.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MCU, Reset to Active ⁽¹⁾		8	350 - 4000		μs
MCU, Shutdown to Active ⁽¹⁾		850 - 4000			μs
MCU, Standby to Active		160			μs
MCU, Active to Standby			39		μs
MCU, Idle to Active			15		μs

(1) The wakeup time is dependent on remaining charge on VDDR capacitor when starting the device, and thus how long the device has been in Reset or Shutdown before starting up again. The wake up time increases with a higher capacitor value.



8.18.3 Clock Specifications

8.18.3.1 48 MHz Clock Input (TCXO)

Measured on a Texas Instruments reference design with $T_c = 25$ °C, $V_{DDS} = 3.0$ V, unless otherwise noted.⁽¹⁾

PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
Clock frequency			48	MHz
TCXO clipped sine output, peak-to-peak	TCXO clipped sine output connected to pin X48M_P through series capacitor	0.8	1.7	V
TCXO with CMOS output, High input voltage	TCXO with CMOS output	1.3	VDDR	V
TCXO with CMOS output, Low input voltage	directly coupled to pin X48M_P	0	0.3	V

(1) Probing or otherwise stopping the TCXO while the DC/DC converter is enabled may cause permanent damage to the device.

8.18.3.2 48 MHz Crystal Oscillator (XOSC_HF)

Measured on a Texas Instruments reference design with $T_c = 25 \text{ °C}$, $V_{DDS} = 3.0 \text{ V}$, unless otherwise noted.⁽¹⁾

	PARAMETER	MIN	TYP	MAX	UNIT
	Crystal frequency		48		MHz
ESR	Equivalent series resistance 6 pF < C _L ≤ 9 pF		20	60	Ω
ESR	Equivalent series resistance 5 pF < C _L ≤ 6 pF			80	Ω
L _M	Motional inductance, relates to the load capacitance that is used for the crystal (CL in Farads) $^{(5)}$		$< 3 \times 10^{-25} / C_{L}^{2}$		н
CL	Crystal load capacitance ⁽⁴⁾	5	7 ⁽³⁾	9	pF
	Start-up time ⁽²⁾		200		μs

(1) Probing or otherwise stopping the crystal while the DC/DC converter is enabled may cause permanent damage to the device.

(2) Start-up time using the TI-provided power driver. Start-up time may increase if driver is not used.

(3) On-chip default connected capacitance including reference design parasitic capacitance. Connected internal capacitance is changed through software in the Customer Configuration section (CCFG).

(4) Adjustable load capacitance is integrated into the device. External load capacitors are required for systems targeting compliance with certain regulations. See the device errata for further details.

(5) The crystal manufacturer's specification must satisfy this requirement for proper operation.

8.18.3.3 48 MHz RC Oscillator (RCOSC_HF)

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Frequency		48		MHz
Uncalibrated frequency accuracy		±1		%
Calibrated frequency accuracy ⁽¹⁾		±0.25		%
Start-up time		5		μs

(1) Accuracy relative to the calibration source (XOSC_HF)

8.18.3.4 2 MHz RC Oscillator (RCOSC_MF)

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency		2		MHz
Start-up time		5		μs

8.18.3.5 32.768 kHz Crystal Oscillator (XOSC_LF)

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	ТҮР	MAX	UNIT
Crystal frequency		32.768		kHz



8.18.3.5 32.768 kHz Crystal Oscillator (XOSC_LF) (continued)

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

		MIN	TYP	MAX	UNIT
ESR	Equivalent series resistance		30	100	kΩ
CL	Crystal load capacitance	6	7 ⁽¹⁾	12	pF

(1) Default load capacitance using TI reference designs including parasitic capacitance. Crystals with different load capacitance may be used.

8.18.3.6 32 kHz RC Oscillator (RCOSC_LF)

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency		32.8 ⁽¹⁾		kHz
Temperature coefficient.	50		ppm/°C	

(1) When using RCOSC_LF as source for the low frequency system clock (SCLK_LF), the accuracy of the SCLK_LF-derived Real Time Clock (RTC) can be improved by measuring RCOSC_LF relative to XOSC_HF and compensating for the RTC tick speed. This functionality is available through the TI-provided Power driver.

8.18.4 Serial Peripheral Interface (SPI) Characteristics

8.18.4.1 SPI Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		Master Mode 1.8 < VDDS < 3.8			12	
f _{SCLK} 1/t _{sclk}	SPI clock frequency	Slave Mode 2.7 < VDDS < 3.8			8	MHz
		Slave Mode VDDS < 2.7			7	
DC _{SCK}	SCK Duty Cycle		45	50	55	%

8.18.4.2 SPI Master Mode

over operating free-air temperature range (unless otherwise noted)

PARAMETERS		TEST CONDITIONS	MIN	TYP MA	X	UNIT
t _{SCLK_H/} L	SCLK High or Low time		(t _{SPI} /2) - 1	t _{SPI} / 2 (t _{SPI} /2) + 1	ns
t _{CS.LEAD}	CS lead-time, CS active to clock		1			SCLK
t _{CS.LAG}	CS lag time, Last clock to CS inactive		1			SCLK
t _{CS.ACC}	CS access time, CS active to MOSI data out				1	SCLK
t _{CS.DIS}	CS disable time, CS inactive to MOSI high inpedance				1	SCLK
t _{SU.MI}	MISO input data setup time ⁽¹⁾	VDDS = 3.3V	12.5			ns
t _{SU.MI}	MISO input data setup time	VDDS = 1.8V	23.5			ns
t _{HD.MI}	MISO input data hold time		0			ns
t _{VALID.M} O	MOSI output data valid time ⁽²⁾	SCLK edge to MOSI valid,CL = 20 pF (4)			13	ns
t _{HD.MO}	MOSI output data hold time ⁽³⁾	CL = 20 pF	0			ns

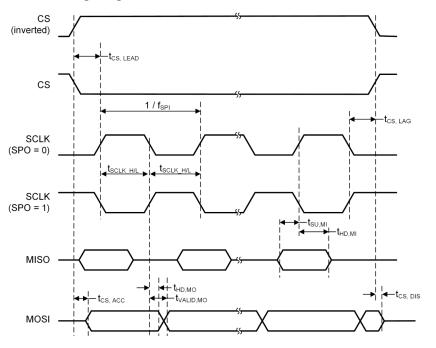
(1) The MISO input data setup time can be fully compensated when delayed sampling feature is enabled.

(2) Specifies the time to drive the next valid data to the output after the output changing SCLK clock edge

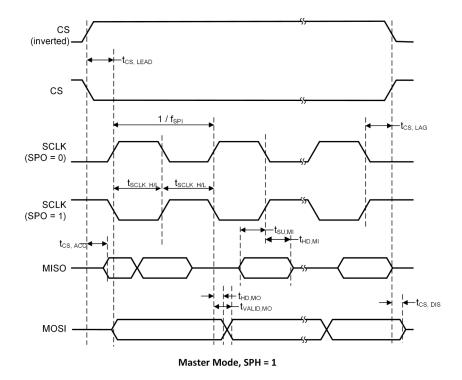
(3)

Specifies how long data on the output is valid after the output changing SCLK clock edge

8.18.4.3 SPI Master Mode Timing Diagrams



Master Mode, SPH = 0



🛛 8-1. SPI Master Mode Timing



8.18.4.4 SPI Slave Mode

over operating free-air temperature range (unless otherwise noted)

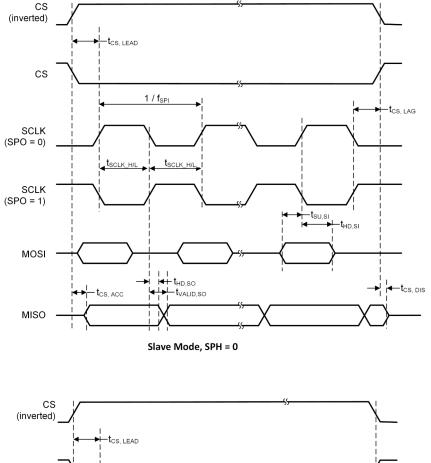
	PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{CS.LEAD}	CS lead-time, CS active to clock		1			SCLK
t _{CS.LAG}	CS lag time, Last clock to CS inactive		1			SCLK
t _{CS.ACC}	CS access time, CS active to MISO data out	VDDS = 3.3V			56	ns
t _{CS.ACC}	CS access time, CS active to MISO data out	VDDS = 1.8V			70	ns
t _{CS.DIS}	CS disable time, CS inactive to MISO high inpedance	VDDS = 3.3V			56	ns
t _{CS.DIS}	CS disable time, CS inactive to MISO high inpedance	VDDS = 1.8V			70	ns
t _{SU.SI}	MOSI input data setup time		30			ns
t _{HD.SI}	MOSI input data hold time		0			ns
t _{VALID.S} O	MISO output data valid time ⁽¹⁾	SCLK edge to MISO valid,C _L = 20 pF, 3.3V (4)			50	ns
t _{VALID.S} O	MISO output data valid time ⁽¹⁾	SCLK edge to MISO valid,C _L = 20 pF, 1.8V (4)			65	ns
t _{HD.SO}	MISO output data hold time ⁽²⁾	C _L = 20 pF	0			ns

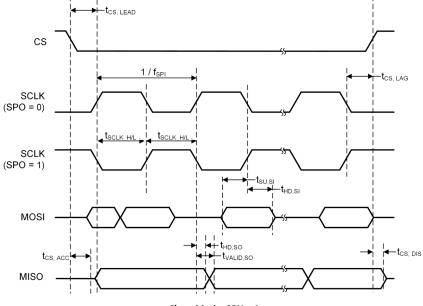
(1) Specifies the time to drive the next valid data to the output after the output changing SCLK clock edge

(2) Specifies how long data on the output is valid after the output changing SCLK clock edge



8.18.4.5 SPI Slave Mode Timing Diagrams





Slave Mode, SPH = 1

8-2. SPI Slave Mode Timing



8.18.5 UART

8.18.5.1 UART Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	MIN	ТҮР	MAX	UNIT
UART rate			3	MBaud

8.19 Peripheral Characteristics

8.19.1 ADC

8.19.1.1 Analog-to-Digital Converter (ADC) Characteristics

 $T_c = 25 \text{ °C}$, $V_{DDS} = 3.0 \text{ V}$ and voltage scaling enabled, unless otherwise noted.⁽¹⁾ Performance numbers require use of offset and gain adjustements in software by TI-provided ADC drivers.

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
	Input voltage range		0	VDDS	V
	Resolution		12		Bits
	Sample Rate			200	ksps
	Offset	Internal 4.3 V equivalent reference ⁽²⁾	-0.24		LSB
	Gain error	Internal 4.3 V equivalent reference ⁽²⁾	7.14		LSB
DNL ⁽⁴⁾	Differential nonlinearity		>-1		LSB
NL	Integral nonlinearity		±4		LSB
		Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone	9.8		
		Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone, DC/DC enabled	9.8		
		VDDS as reference, 200 kSamples/s, 9.6 kHz input tone	10.1		
ENOB I	Effective number of bits	Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	11.1		Bits
		Internal reference, voltage scaling disabled, 14-bit mode, 200 kSamples/s, 300 Hz input tone ⁽⁵⁾	11.3		
		Internal reference, voltage scaling disabled, 15-bit mode, 200 kSamples/s, 300 Hz input tone ⁽⁵⁾	11.6		_
		Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone	-65		
9.6 kHz input tone THD Total harmonic distortion VDDS as reference, 200 kSamples/s, 9.6	VDDS as reference, 200 kSamples/s, 9.6 kHz input tone	-70		dB	
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	-72		dB
	Signal-to-noise	Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone	60		
SINAD, SNDR	and	VDDS as reference, 200 kSamples/s, 9.6 kHz input tone	63		dB
	distortion ratio	Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	68	VDDS 200 200 1<	
		Internal 4.3 V equivalent reference ⁽²⁾ , 200 kSamples/s, 9.6 kHz input tone	70		
SFDR	Spurious-free dynamic range	VDDS as reference, 200 kSamples/s, 9.6 kHz input tone	73		dB
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	75		
	Conversion time	Serial conversion, time-to-output, 24 MHz clock	50		Clock Cycle
	Current consumption	Internal 4.3 V equivalent reference ⁽²⁾	0.42		mA
	Current consumption	VDDS as reference	0.6		mA
	Reference voltage	Equivalent fixed internal reference (input voltage scaling enabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/ offset compensation factors stored in FCFG1	4.3 ^{(2) (3)}		V



8.19.1.1 Analog-to-Digital Converter (ADC) Characteristics (continued)

 T_c = 25 °C, V_{DDS} = 3.0 V and voltage scaling enabled, unless otherwise noted.⁽¹⁾ Performance numbers require use of offset and gain adjustements in software by TI-provided ADC drivers.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reference voltage	Fixed internal reference (input voltage scaling disabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/offset compensation factors stored in FCFG1. This value is derived from the scaled value (4.3 V) as follows: $V_{ref} = 4.3 V \times 1408 / 4095$		1.48		V
Reference voltage	VDDS as reference, input voltage scaling enabled		VDDS		V
Reference voltage	VDDS as reference, input voltage scaling disabled		VDDS / 2.82 ⁽³⁾		V
Input impedance	200 kSamples/s, voltage scaling enabled. Capacitive input, Input impedance depends on sampling frequency and sampling time		>1		MΩ

Using IEEE Std 1241-2010 for terminology and test methods (1)

(2) (3) Input signal scaled down internally before conversion, as if voltage range was 0 to 4.3 V

Applied voltage must be within Absolute Maximum Ratings at all times

(4) (5) No missing codes

ADC_output = $\Sigma(4^n \text{ samples }) >> n, n = \text{desired extra bits}$



8.19.2 DAC

8.19.2.1 Digital-to-Analog Converter (DAC) Characteristics

 T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Genera	I Parameters	r				
	Resolution			8		Bits
		Any load, any V_{REF} , pre-charge OFF, DAC charge-pump ON	1.8		3.8	
/ _{DDS}	Supply voltage	External Load $^{\rm (4)},$ any $\rm V_{\rm REF},$ pre-charge OFF, DAC charge-pump OFF	2.0		3.8	V
		Any load, V _{REF} = DCOUPL, pre-charge ON	2.6		3.8	
	Clock frequency	Buffer ON (recommended for external load)	16		250	kHz
DAC		Buffer OFF (internal load)	16		1000	KI IZ
	Voltage output settling time	V _{REF} = VDDS, buffer OFF, internal load		13		1 / F _{DAC}
	voltage output setting time	V_{REF} = VDDS, buffer ON, external capacitive load = 20 pF ⁽³⁾		13.8		I / I DAC
	External capacitive load			20	200	pF
	External resistive load		10			MΩ
	Short circuit current				400	μA
-		VDDS = 3.8 V, DAC charge-pump OFF		50.8		
		VDDS = 3.0 V, DAC charge-pump ON		51.7		
	Max output impedance Vref =	VDDS = 3.0 V, DAC charge-pump OFF		53.2		
MAX	VDDS, buffer ON, CLK 250	VDDS = 2.0 V, DAC charge-pump ON		48.7		kΩ
	kHz	VDDS = 2.0 V, DAC charge-pump OFF		70.2		
		VDDS = 1.8 V, DAC charge-pump ON		46.3		
		VDDS = 1.8 V, DAC charge-pump OFF		88.9		
nterna	I Load - Continuous Time Com	parator / Low Power Clocked Comparator				
	Differential nonlinearity $V_{REF} = VDDS$, load = Continuous Time Comparator or Low Power Clocked Comparator $F_{DAC} = 250 \text{ kHz}$ ± 1		1.0.0(1)			
DNL	Differential nonlinearity	V _{REF} = VDDS, load = Continuous Time Comparator or Low Power Clocked Comparator F _{DAC} = 16 kHz		±1.2		LSB ⁽¹⁾
		V _{REF} = VDDS = 3.8 V		±0.64		
		V _{REF} = VDDS= 3.0 V		±0.81		
	Offset error ⁽²⁾	V _{REF} = VDDS = 1.8 V		±1.27		(1)
	Load = Continuous Time Comparator	V _{REF} = DCOUPL, pre-charge ON		±3.43		LSB ⁽¹⁾
		V _{REF} = DCOUPL, pre-charge OFF		±2.88		
		V _{REF} = ADCREF		±2.37		
		V _{REF} = VDDS= 3.8 V		±0.78		
				±0.77		
		$V_{REF} = VDDS = 3.0 V$				
	Offset error ⁽²⁾	V _{REF} = VDDS = 3.0 V V _{REF} = VDDS = 1.8 V		±3.46		
	Load = Low Power Clocked					LSB ⁽¹⁾
		V _{REF} = VDDS= 1.8 V		±3.46		LSB ⁽¹⁾
	Load = Low Power Clocked	V _{REF} = VDDS= 1.8 V V _{REF} = DCOUPL, pre-charge ON		±3.46 ±3.44		LSB ⁽¹⁾
	Load = Low Power Clocked	V _{REF} = VDDS= 1.8 V V _{REF} = DCOUPL, pre-charge ON V _{REF} = DCOUPL, pre-charge OFF		±3.46 ±3.44 ±4.70		LSB ⁽¹⁾
	Load = Low Power Clocked Comparator	V _{REF} = VDDS= 1.8 V V _{REF} = DCOUPL, pre-charge ON V _{REF} = DCOUPL, pre-charge OFF V _{REF} = ADCREF		±3.46 ±3.44 ±4.70 ±4.11		LSB ⁽¹⁾
	Load = Low Power Clocked Comparator Max code output voltage	$V_{REF} = VDDS = 1.8 V$ $V_{REF} = DCOUPL, pre-charge ON$ $V_{REF} = DCOUPL, pre-charge OFF$ $V_{REF} = ADCREF$ $V_{REF} = VDDS = 3.8 V$		±3.46 ±3.44 ±4.70 ±4.11 ±1.53		
	Load = Low Power Clocked Comparator Max code output voltage variation ⁽²⁾ Load = Continuous Time	VREF VDDS= 1.8 V VREF DCOUPL, pre-charge ON VREF DCOUPL, pre-charge OFF VREF ADCREF VREF VDDS = 3.8 V VREF VDDS = 3.0 V		±3.46 ±3.44 ±4.70 ±4.11 ±1.53 ±1.71		LSB ⁽¹⁾
	Load = Low Power Clocked Comparator Max code output voltage variation ⁽²⁾	VREF VDDS= 1.8 V VREF DCOUPL, pre-charge ON VREF DCOUPL, pre-charge OFF VREF ADCREF VREF VDDS = 3.8 V VREF VDDS = 3.0 V VREF VDDS = 1.8 V		±3.46 ±3.44 ±4.70 ±4.11 ±1.53 ±1.71 ±2.10		



8.19.2.1 Digital-to-Analog Converter (DAC) Characteristics (continued)

 $T_c = 25 \text{ °C}, V_{DDS} = 3.0 \text{ V}$, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
		V _{REF} = VDDS= 3.8 V	±2.92	
	Max code output voltage	V _{REF} =VDDS= 3.0 V	±3.06	
	variation ⁽²⁾	V _{REF} = VDDS= 1.8 V	±3.91	LSB ⁽¹⁾
	Load = Low Power Clocked Comparator	V _{REF} = DCOUPL, pre-charge ON	±7.84	LOD
	Comparator	V _{REF} = DCOUPL, pre-charge OFF	±4.06	
		V _{REF} = ADCREF	±6.94	
		V _{REF} = VDDS = 3.8 V, code 1	0.03	
		V _{REF} = VDDS = 3.8 V, code 255	3.62	
		V _{REF} = VDDS= 3.0 V, code 1	0.02	
		V _{REF} = VDDS= 3.0 V, code 255	2.86	
		V _{REF} = VDDS= 1.8 V, code 1	0.01	
	Output voltage range ⁽²⁾ Load = Continuous Time	V _{REF} = VDDS = 1.8 V, code 255	1.71	V
	Comparator	V _{REF} = DCOUPL, pre-charge OFF, code 1	0.01	v
		V _{REF} = DCOUPL, pre-charge OFF, code 255	1.21	
		V _{REF} = DCOUPL, pre-charge ON, code 1	1.27	
		V _{REF} = DCOUPL, pre-charge ON, code 255	2.46	
		V _{REF} = ADCREF, code 1	0.01	
		V _{REF} = ADCREF, code 255	1.41	
		V _{REF} = VDDS = 3.8 V, code 1	0.03	
		V _{REF} = VDDS= 3.8 V, code 255	3.61	
		V _{REF} = VDDS= 3.0 V, code 1	0.02	
		V _{REF} = VDDS= 3.0 V, code 255	2.85	
		V _{REF} = VDDS = 1.8 V, code 1	0.01	
	Output voltage range ⁽²⁾	V _{REF} = VDDS = 1.8 V, code 255	1.71	
	Load = Low Power Clocked Comparator	V _{REF} = DCOUPL, pre-charge OFF, code 1	0.01	V
		V _{REF} = DCOUPL, pre-charge OFF, code 255	1.21	
		V _{REF} = DCOUPL, pre-charge ON, code 1	1.27	
		V _{REF} = DCOUPL, pre-charge ON, code 255	2.46	
		V _{REF} = ADCREF, code 1	0.01	
		V _{REF} = ADCREF, code 255	1.41	
xterna	al Load (Keysight 34401A Mult	imeter)		
		V _{REF} = VDDS, F _{DAC} = 250 kHz	±1	
۱L	Integral nonlinearity	V _{REF} = DCOUPL, F _{DAC} = 250 kHz	±1	LSB ⁽¹⁾
		V _{REF} = ADCREF, F _{DAC} = 250 kHz	±1	LSB ⁽¹⁾
NL	Differential nonlinearity	V _{REF} = VDDS, F _{DAC} = 250 kHz	±1	LSB ⁽¹⁾
		V _{REF} = VDDS= 3.8 V	±0.20	
		V _{REF} = VDDS= 3.0 V	±0.25	
		V _{REF} = VDDS = 1.8 V	±0.45	
	Offset error	V _{REF} = DCOUPL, pre-charge ON	±1.55	LSB ⁽¹⁾
		V _{REF} = DCOUPL, pre-charge OFF	±1.30	
		V _{REF} = ADCREF	±1.10	
		V _{REF} = VDDS= 3.8 V	±0.60	
		V _{REF} = VDDS= 3.0 V	±0.55	
	Max code output voltage	V _{REF} = VDDS= 1.8 V	±0.60	
	variation	V _{REF} = DCOUPL, pre-charge ON	±3.45	LSB ⁽¹⁾
		V_{REF} = DCOUPL, pre-charge OFF	±2.10	
		$V_{REF} = DOCOLE, provincing COLLV_{REF} = ADCREF$	±1.90	



8.19.2.1 Digital-to-Analog Converter (DAC) Characteristics (continued)

 $T_c = 25 \text{ °C}, V_{DDS} = 3.0 \text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	V _{REF} = VDDS = 3.8 V, code 1		0.03		
	V _{REF} = VDDS = 3.8 V, code 255		3.61		
	V _{REF} = VDDS = 3.0 V, code 1		0.02		
	V _{REF} = VDDS= 3.0 V, code 255		2.85		
	V _{REF} = VDDS= 1.8 V, code 1		0.02		
Output voltage range Load = Low Power Clocked	V _{REF} = VDDS = 1.8 V, code 255		1.71		V
Comparator	V _{REF} = DCOUPL, pre-charge OFF, code 1		0.02		v
	V _{REF} = DCOUPL, pre-charge OFF, code 255		1.20		
	V _{REF} = DCOUPL, pre-charge ON, code 1		1.27		
	V _{REF} = DCOUPL, pre-charge ON, code 255		2.46		
	V _{REF} = ADCREF, code 1		0.02		
	V _{REF} = ADCREF, code 255		1.42		

(1) 1 LSB (V_{REF} 3.8 V/3.0 V/1.8 V/DCOUPL/ADCREF) = 14.10 mV/11.13 mV/6.68 mV/4.67 mV/5.48 mV

(2) Includes comparator offset

(3) A load > 20 pF will increases the settling time

(4) Keysight 34401A Multimeter



8.19.3 Temperature and Battery Monitor

8.19.3.1 Temperature Sensor

Measured on a Texas Instruments reference design with T_c = 25 °C, V_{DDS} = 3.0 V, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			2		°C
Accuracy	-40 °C to 0 °C		±4.0		°C
Accuracy	0 °C to 105 °C		±2.5		°C
Supply voltage coefficient ⁽¹⁾			3.6		°C/V

(1) The temperature sensor is automatically compensated for VDDS variation when using the TI-provided driver.

8.19.3.2 Battery Monitor

Measured on a Texas Instruments reference design with T_c = 25 °C, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			25		mV
Range		1.8		3.8	V
Integral nonlinearity (max)			23		mV
Accuracy	VDDS = 3.0 V		22.5		mV
Offset error			-32		mV
Gain error			-1		%

8.19.4 Comparators

8.19.4.1 Low-Power Clocked Comparator

 $T_c = 25 \text{ °C}$, $V_{DDS} = 3.0 \text{ V}$, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range		0		V _{DDS}	V
Clock frequency			SCLK_LF		
Internal reference voltage ⁽¹⁾	Using internal DAC with VDDS as reference voltage, DAC code = 0 - 255	0.0)24 - 2.865		V
Offset	Measured at V _{DDS} / 2, includes error from internal DAC		±5		mV
Decision time	Step from –50 mV to 50 mV		1		Clock Cycle

(1) The comparator can use an internal 8 bits DAC as its reference. The DAC output voltage range depends on the reference voltage selected. See DAC Characteristics

8.19.4.2 Continuous Time Comparator

 T_c = 25°C, V_{DDS} = 3.0 V, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
Input voltage range ⁽¹⁾		0		V _{DDS}	V
Offset	Measured at V _{DDS} / 2		±5		mV
Decision time	Step from –10 mV to 10 mV		0.78		μs
Current consumption	Internal reference		8.6		μΑ

(1) The input voltages can be generated externally and connected throughout I/Os or an internal reference voltage can be generated using the DAC

8.19.5 Current Source

8.19.5.1 Programmable Current Source

 $T_c = 25$ °C, $V_{DDS} = 3.0$ V, unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Current source programmable output range (logarithmic range)		0.25 - 20		μA
Resolution		0.25		μA



8.19.6 GPIO

8.19.6.1 GPIO DC Characteristics

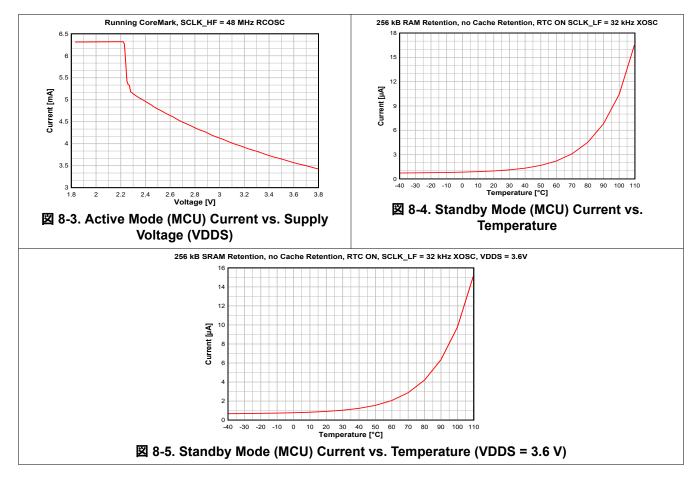
PARAMETER	TEST CONDITIONS	MIN TYP MA	
T _A = 25 °C, V _{DDS} = 1.8 V			
GPIO VOH at 8 mA load	at 8 mA load IOCURR = 2, high-drive GPIOs only 1.56		V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only	GPIOs only 0.24	
GPIO VOH at 4 mA load	IOCURR = 1	1.59	
GPIO VOL at 4 mA load	IOCURR = 1	0.21	V
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V	73	μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDDS	19	μA
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as $0 \rightarrow 1$	1.08	V
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as $1 \rightarrow 0$	0.73	V
GPIO input hysteresis	IH = 1, difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.35	
T _A = 25 °C, V _{DDS} = 3.0 V			
GPIO VOH at 8 mA load	IOCURR = 2, high-drive GPIOs only	2.59	V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only	0.42	
GPIO VOH at 4 mA load	IOCURR = 1	2.63	
GPIO VOL at 4 mA load	IOCURR = 1	0.40	
T _A = 25 °C, V _{DDS} = 3.8 V			
GPIO pullup current	Input mode, pullup enabled, Vpad = 0 V	282	μA
GPIO pulldown current	Input mode, pulldown enabled, Vpad = VDDS	110	
GPIO low-to-high input transition, with hysteresis	IH = 1, transition voltage for input read as $0 \rightarrow 1$	1.97	
GPIO high-to-low input transition, with hysteresis	IH = 1, transition voltage for input read as $1 \rightarrow 0$	1.55	
GPIO input hysteresis	IH = 1, difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.42	
T _A = 25 °C			
VIH	Lowest GPIO input voltage reliably interpreted as a High	a 0.8*V _{DDS}	
VIL	Highest GPIO input voltage reliably interpreted as a Low	0.2*V _D	os V



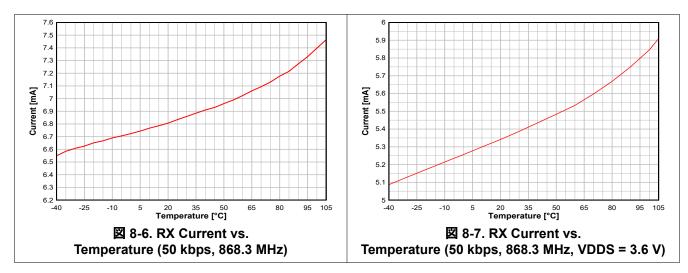
8.20 Typical Characteristics

All measurements in this section are done with $T_c = 25$ °C and $V_{DDS} = 3.0$ V, unless otherwise noted. See *Recommended Operating Conditions*, 222×8.3 , for device limits. Values exceeding these limits are for reference only.

8.20.1 MCU Current



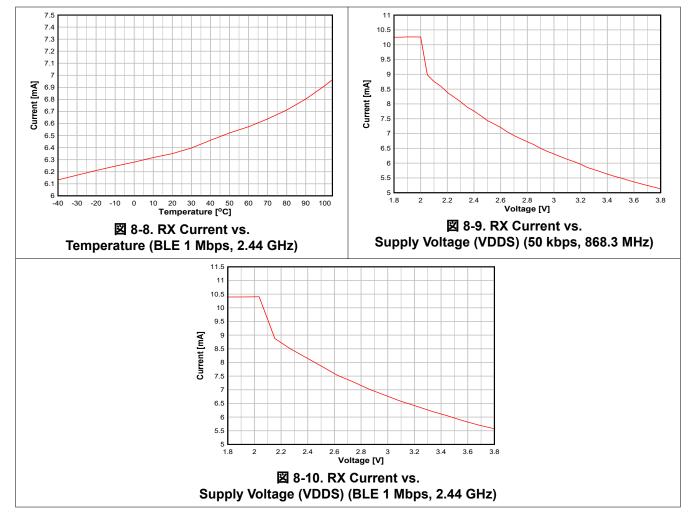
8.20.2 RX Current



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8.20.3 TX Current

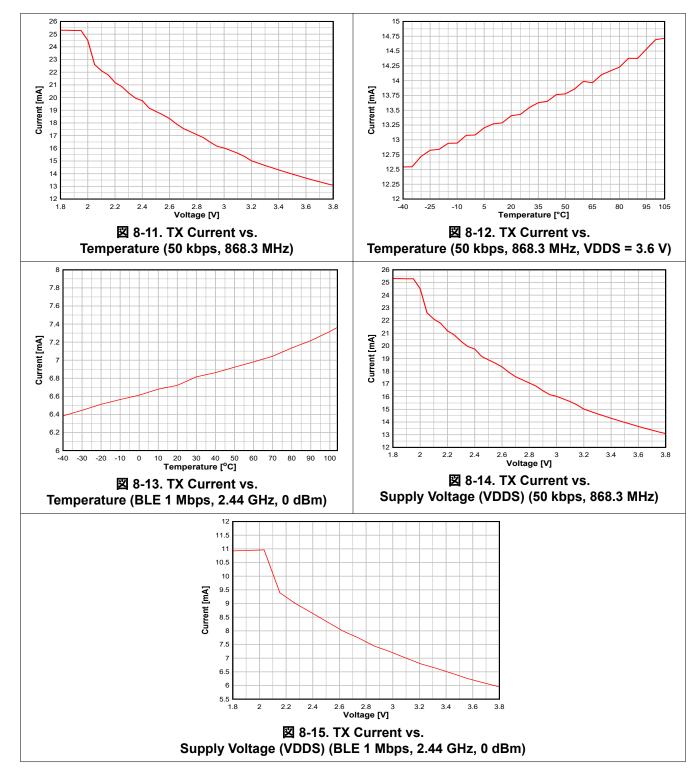




表 8-1 and 表 8-2 show typical TX current and output power for different output power settings. 表 8-1. Typical TX Current and Output Power (868 MHz, VDDS = 3.6 V)

txPowerTX Power Setting (SmartRF Studie)Typical Output Power (IdBm)Typical Current Consumption (mA)0x1351414.024.30x80281212.017.20x785411111.015.10x26040.1010.11.013.50x704499.0012.60x1645588.0012.20x146507.77.70111.20x14555.55.5019.60x145544.009.99.00x145555.5019.69.10x14543.2989.19.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.09.99.10x14540.11.07.99.10x12541.10.098.20x12540.19.99.10x12640.19.99.10x12651.49.99.10x12641.49.99.10x12651.49.99.10x12651.49.99.10x12641.49.99.10x12651.49.99.10x12651.49.99.10x12651.49.9	CC1354R at 868 MHz, VDDS = 3.6 V (Measured on CC1354R10EM-7X7-XD7793-XD24)				
0x802B 12 12.0 17.2 0x785E 11 11.0 15.1 0x785E 11 10.1 13.5 0x70A4 9 9.00 12.6 0x16A66 8 8.00 12.2 0x14E5D 7 7.01 11.2 0x14057 6 6.08 10.4 0x55E 5 5.01 9.6 0x14833 4 4.00 9.9 0x14249 3 2.98 9.1 0x1124 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A98 0 0.11 7.5 0x1328E -2 -2.00 7.6 0x1328E -2 -2.00 7.6 0x12A4 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x110D -6 6.66 6.0 0x20EFF -8 -7.96 7.0 <	txPower	TX Power Setting (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]	
0x785E 11 11.0 15.1 0x2E04 10 10.1 13.5 0x7044 9 9.00 12.6 0x16A66 8 8.00 12.2 0x16A67 6 6.08 10.4 0x14650 7 7.01 11.2 0x14057 6 6.08 10.4 0x5CE5 5 5.01 9.6 0x14583 4 4.00 9.9 0x14E49 3 2.98 9.1 0x1124A 2 2.13 8.2 0x1329C 1 1.00 7.9 0x13248 0 0.11 7.5 0x13244 -3 -2.99 7.1 0x1244 -3 2.99 7.1 0x1244 -3 -2.99 7.1 0x1245 -4 3.3 -2.99 0x1264 -3 -2.99 7.1 0x2164 -6 6.6 6.0	0x13F	14	14.0	24.3	
Dx2E04 10 10.1 13.5 Dx70A4 9 9.00 12.6 Dx16A66 8 8.00 12.2 Dx14E5D 7 7.01 11.2 Dx14D57 6 6.08 10.4 Ox5CE5 5 5.01 9.6 Ox158B3 4 4.00 9.9 Dx14EA9 3 2.98 9.1 Ox1024 2 2.13 8.2 Ox13202 1 1.00 7.9 Ox12489 0 0.11 7.5 Ox1324 -1 -0.99 8.2 Ox13248 -2 -2.00 7.6 Ox12A84 -3 -2.99 7.1 Ox12A84 -3 -2.99 7.1 Ox12A84 -3 -2.99 7.1 Ox12A84 -3 -7.6 -2.00 Ox110A0 -6 6.6 6.0 Ox20EF7 -7 -7.01 7.5	0xB02B	12	12.0	17.2	
0x70A4 9 9.00 12.6 0x16A66 8 8.00 12.2 0x14E5D 7 7.01 11.2 0x14057 6 6.08 10.4 0x5CE5 5 5.01 9.6 0x15B3 4 4.00 9.9 0x14EA9 3 2.98 9.1 0x1104A 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A8 0 0.11 7.5 0x1329C 1 -0.99 8.2 0x1328 -2 -2.00 7.6 0x13244 -3 -2.99 7.1 0x21045 -4 -3.95 7.2 0x1102A -5 -4.98 6.3 0x11626 -6 -6.06 6.0 0x20167 -7 -7.01 7.5 0x20267 -7 -7.01 7.5 0x20267 -13 -12.0 5.7	0x785E	11	11.0	15.1	
0x16A66 8 8.00 12.2 0x14E5D 7 7.01 11.2 0x14057 6 6.08 10.4 0x5CE5 5 5.01 9.6 0x15883 4 4.00 9.9 0x16A6 2.98 9.1 0.1 0x1624 2 2.13 8.2 0x1329C 1 1.00 7.9 0x13284 0 0.11 7.5 0x13285 -2 -2.00 7.6 0x12424 -3 -2.99 7.1 0x12A8 4 -3.95 7.2 0x13285 -2 -2.00 7.6 0x12A8 -4 -3.95 7.2 0x110DA -5 -4.98 6.3 0x110DA -5 -4.98 6.3 0x116D6 -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x20BD5 -11 -10.9 5.9	0x2E04	10	10.1	13.5	
0x14E5D 7 7.01 11.2 0x14057 6 6.08 10.4 0x5CE5 5 5.01 9.6 0x158B3 4 4.00 9.9 0x14E49 3 2.98 9.1 0x11244 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12488 0 0.11 7.5 0x132F4 -1 -0.99 8.2 0x132E8 -2 -2.00 7.6 0x12A84 -3 2.99 7.1 0x12A84 -3 -2.99 7.1 0x12A84 -3 -2.99 7.1 0x12A8 4 -3.95 7.2 0x112A -5 -4.98 6.3 0x112A -5 -4.98 6.3 0x11DA -5 -4.98 6.3 0x110D -6 -6.06 6.0 0x20EF -8 -7.96 7.0	0x70A4	9	9.00	12.6	
0x14057 6 6.08 10.4 0x5CE5 5 5.01 9.6 0x158B3 4 4.00 9.9 0x14EA9 3 2.98 9.1 0x112A4 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A88 0 0.11 7.5 0x132F4 -1 -0.99 8.2 0x132E8 -2 -2.00 7.6 0x12A84 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x300A8 -10 -9.94 6.8 0x20EB5 -8 -7.96 7.0 0x20EB6 -9.00 6.5 0x300A7 -11 -10.9 5.9 0x20B7 -13 -12.8 5.4 0x3	0x16A66	8	8.00	12.2	
0x5CE5 5 5.01 9.6 0x158B3 4 4.00 9.9 0x14EA9 3 2.98 9.1 0x11C4A 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A98 0 0.11 7.5 0x132B4 -1 -0.99 8.2 0x132E8 -2 -2.00 7.6 0x12A84 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -5 -4.98 6.3 0x11CDA -5 -4.98 6.3 0x11CDA -6 -6.06 6.0 0x20EF7 -7 7.01 7.5 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x20BD -11 -10.9 5.9 0x20BDA -12 -12.0 5.7	0x14E5D	7	7.01	11.2	
0x15883 4 4.00 9.9 0x14EA9 3 2.98 9.1 0x11C4A 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A88 0 0.11 7.5 0x1328C -1 -0.99 8.2 0x1328B -2 -2.00 7.6 0x12A84 -3 -2.99 7.1 0x12A8 -4 -3.95 7.2 0x11D6 -6 -6.06 6.0 0x20EF7 -7 7.01 7.5 0x20EE8 -9 -9.00 6.5 0x300A -11 -10.9 5.9 0x20BD -11 -10.9 5.4	0x14057	6	6.08	10.4	
0x14EA9 3 2.98 9.1 0x11C4A 2 2.13 8.2 0x1329C 1 1.00 7.9 0x12A98 0 0.11 7.5 0x138F4 -1 -0.99 8.2 0x132EB -2 -2.00 7.6 0x12A84 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x300AB -10 -9.94 6.8 0x300AB -10 -9.94 6.8 0x20EF7 -7 -7.01 7.0 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x20BD7 -13 -12.8 5.4 0x300F0 -14 -14.0 6.8 0x300E4 -16 -16.1 6.1	0x5CE5	5	5.01	9.6	
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0x1329C 1 1.00 7.9 0x12A98 0 0.11 7.5 0x138F4 -1 -0.99 8.2 0x132EB -2 -2.00 7.6 0x12AE4 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -5 -4.98 6.3 0x11CDA -5 -4.98 6.3 0x11CDA -5 -7.01 7.5 0x20EF7 -7 -7.01 7.5 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x208DE -11 -10.9 5.9 0x208DA -12 -12.0 5.7 0x208D7 -13 -12.8 5.4 0x3008A -15 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x300E4 -16 -16.1 6.1	0x14EA9	3	2.98	9.1	
0x12A98 0 0.11 7.5 0x138F4 -1 -0.99 8.2 0x132E8 -2 -2.00 7.6 0x12AE4 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x20EF8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x20BE4 -13 -12.8 5.4 0x20BD5 -13 -12.8 5.4 0x300B4 -15 -14.9 6.8 0x300E4 -16 -16.1 6.1 0x300E4 -16 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x300E4 -16 -16.1 6.1 0x300E4 -17 -17.0 5.8 0x300E4 -18 -18.0 5.6	0x11C4A	2	2.13	8.2	
0x138F4 -1 -0.99 8.2 0x132EB -2 -2.00 7.6 0x12AE4 -3 -2.99 7.1 0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x11CDA -5 -4.98 6.3 0x11CDA -5 -7.01 7.2 0x11CDA -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x20EF8 -8 -7.96 7.0 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x20BDE -11 -10.9 5.9 0x20BDA -12 -12.0 5.7 0x20BD7 -13 -12.8 5.4 0x300E4 -14 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x300E4 -16 -16.1 6.1 0x300E4 -17 -17.0 5.8	0x1329C	1	1.00	7.9	
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0x21CA8 -4 -3.95 7.2 0x11CDA -5 -4.98 6.3 0x116D6 -6 -6.06 6.0 0x20EF7 -7 -7.01 7.5 0x20EEF -8 -7.96 7.0 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x208DE -11 -10.9 5.9 0x208DA -12 -12.0 5.7 0x208D7 -13 -12.8 5.4 0x300E4 -15 -14.9 6.8 0x300E4 -15 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6	0x132EB	-2	-2.00	7.6	
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0x116D6-6-6.066.00x20EF7-7-7.017.50x20EFF-8-7.967.00x20EE8-9-9.006.50x300AB-10-9.946.80x208DE-11-10.95.90x208DA-12-12.05.70x208D7-13-12.85.40x300EA-15-14.96.40x300E4-16-16.16.10x300E0-17-17.05.80x300DC-18-18.05.60x300D9-19-19.65.3	0x21CA8	-4	-3.95	7.2	
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0x20EEF -8 -7.96 7.0 0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x208DE -11 -10.9 5.9 0x208DA -12 -12.0 5.7 0x208D7 -13 -12.8 5.4 0x300EA -15 -14.9 6.8 0x300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6	0x116D6	-6	-6.06	6.0	
0x20EE8 -9 -9.00 6.5 0x300AB -10 -9.94 6.8 0x208DE -11 -10.9 5.9 0x208DA -12 -12.0 5.7 0x208D7 -13 -12.8 5.4 0x300EA -14 -14.0 6.8 0x300EA -15 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6	0x20EF7	-7	-7.01	7.5	
0x300AB-10-9.946.80x208DE-11-10.95.90x208DA-12-12.05.70x208D7-13-12.85.40x308F0-14-14.06.80x300EA-15-14.96.40x300E4-16-16.16.10x308E0-17-17.05.80x300DC-18-18.05.60x300D9-19-19.65.3	0x20EEF	-8	-7.96	7.0	
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0x308F0 -14 -14.0 6.8 0x300EA -15 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6 0x300D9 -19 -19.6 5.3	0x208DA	-12	-12.0	5.7	
Ox300EA -15 -14.9 6.4 0x300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6 0x300D9 -19 -19.6 5.3	0x208D7	-13	-12.8	5.4	
Ox300E4 -16 -16.1 6.1 0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6 0x300D9 -19 -19.6 5.3	0x308F0	-14	-14.0	6.8	
0x308E0 -17 -17.0 5.8 0x300DC -18 -18.0 5.6 0x300D9 -19 -19.6 5.3	0x300EA	-15	-14.9	6.4	
0x300DC -18 -18.0 5.6 0x300D9 -19 -19.6 5.3	0x300E4	-16	-16.1	6.1	
0x300D9 -19 -19.6 5.3	0x308E0	-17	-17.0	5.8	
	0x300DC	-18	-18.0	5.6	
0x300D6 -20 -20.0 5.2	0x300D9	-19	-19.6	5.3	
	0x300D6	-20	-20.0	5.2	

表 8-2. Typical TX Current and Output Power (2.4 GHz, VDDS = 3.0 V)

CC1354R at 2.4 GHz, VDDS = 3.0 V (Measured on CC1354R10EM-7X7-XD7793-XD24)				
txPower	TX Power Setting (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]	
0x7217	5	4.4	9.6	
0x4E63	4	3.0	8.9	
0x385D	3	1.8	8.3	
0x3259	2	0.7	7.9	
0x2856	1	-0.3	7.5	
0x2853	0	-1.5	7.1	

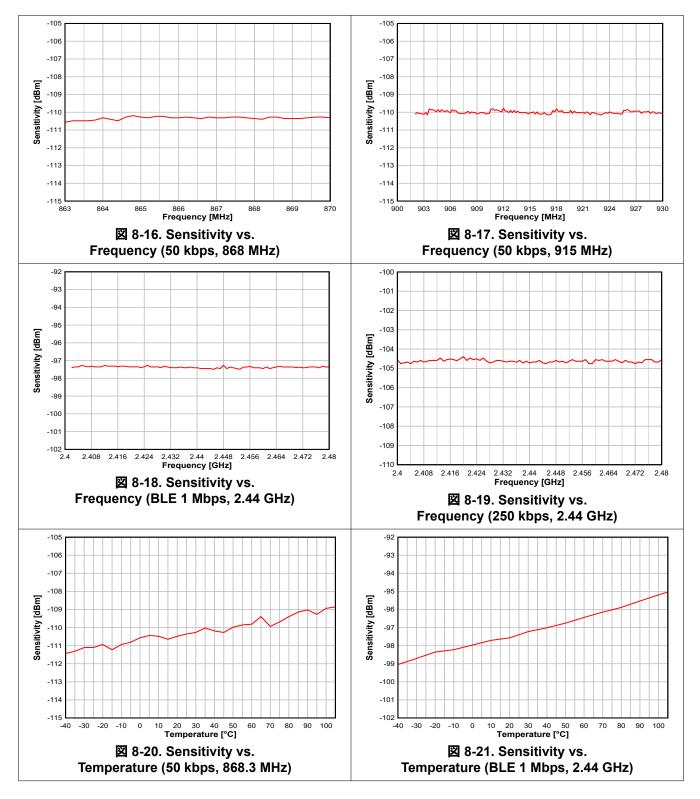


|--|

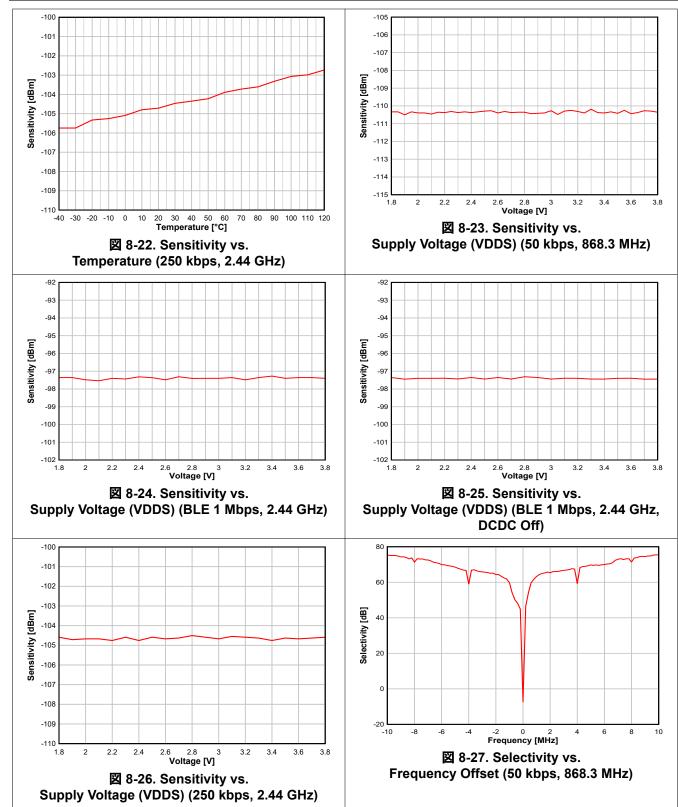
	CC1354R at 2.4 GHz, VDDS = 3.0 V (Measured on CC1354R10EM-7X7-XD7793-XD24)				
txPower	TX Power Setting (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]		
0x12D6	-5	-6.7	6.1		
0x0ACF	-10	-11.5	5.5		
0x06CA	-15	-16.7	5.1		
0x04C6	-20	-22.7	4.8		



8.20.4 RX Performance

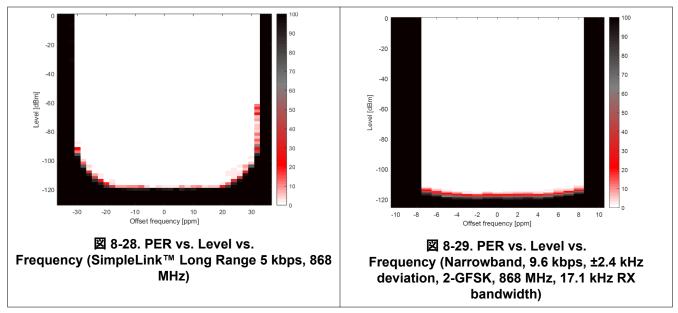






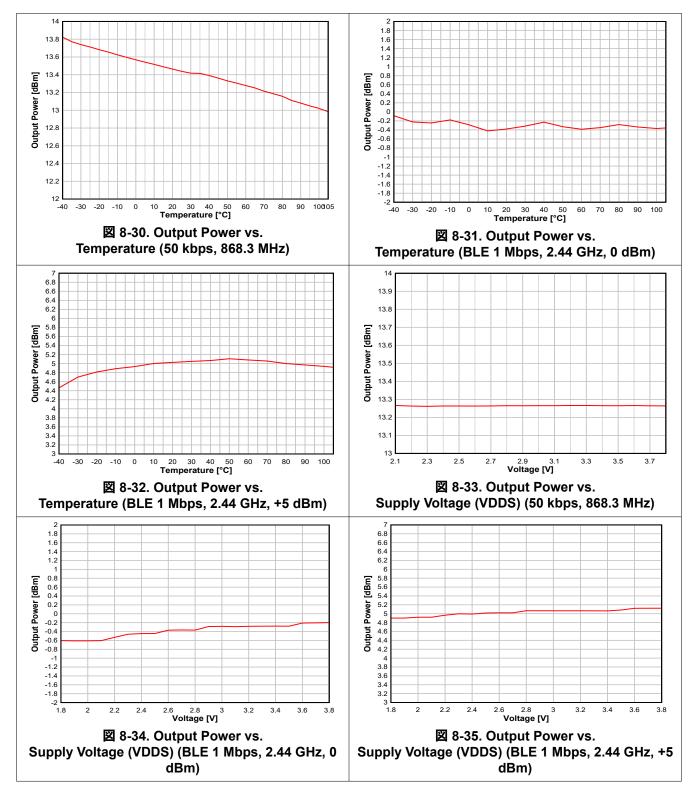
CC1354R10 JAJSQQ5A – DECEMBER 2022 – REVISED JUNE 2023





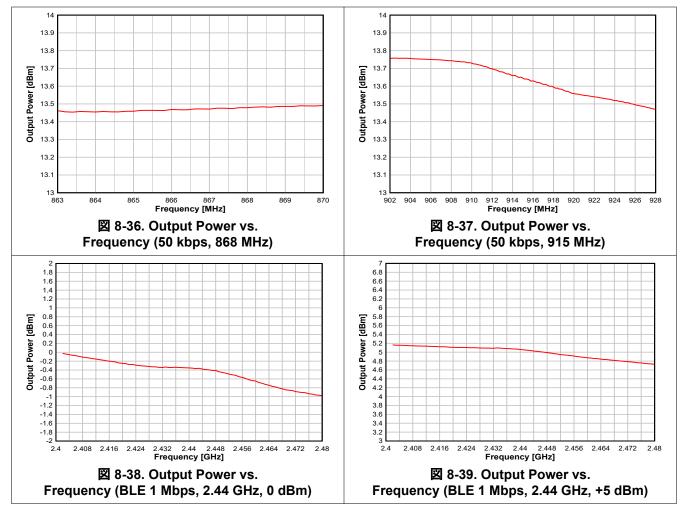


8.20.5 TX Performance



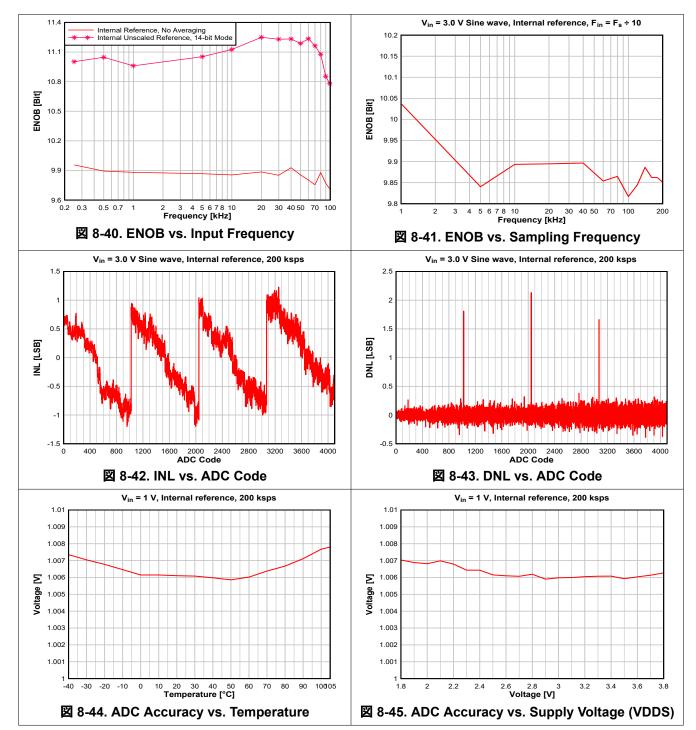
CC1354R10 JAJSQQ5A – DECEMBER 2022 – REVISED JUNE 2023







8.20.6 ADC Performance





9 Detailed Description

9.1 Overview

セクション 4 shows the core modules of the CC1354R10 device.

Throughout this section, see the Technical Reference Manual listed in Section 11.2 for more details.

9.2 System CPU

The CC1354R10 SimpleLink[™] Wireless MCU contains an Arm[®] Cortex[®]-M33 system CPU with TrustZone[®], which runs the application and the higher layers of radio protocol stacks.

The system CPU is the foundation of a high-performance, low-cost platform that meets the system requirements of minimal memory implementation, and low-power consumption, while delivering outstanding computational performance and exceptional system response to interrupts.

Its features include the following:

- ARMv8-M architecture with TrustZone[®] security extension optimized for small-footprint embedded applications
- Arm Thumb[®]-2 mixed 16- and 32-bit instruction set delivers the high performance expected of a 32-bit Arm core in a compact memory size
- 8 regions of non-secure memory protected regions
- 8 regions of secure memory protected regions
- 4 regions of Security Attribute Unit (SAU)
- Single-cycle multiply instruction and hardware divide
- Digital-signal-processing (DSP) extension
- IEEE 754-compliant single-precision Floating Point Unit (FPU)
- Fast code execution permits increased sleep mode time
- Deterministic, high-performance interrupt handling for time-critical applications
- Full debug with data matching for watchpoint generation
 - Data Watchpoint and Trace Unit (DWT)
 - JTAG Debug Access Port (DAP)
- Flash Patch and Breakpoint Unit (FPB)
- Trace support reduces the number of pins required for debugging and tracing
 - Instrumentation Trace Macrocell Unit (ITM)
 - Trace Port Interface Unit (TPIU) with asynchronous serial wire output (SWO)
 - Optimized for single-cycle flash memory access
- Tightly connected to 8 kB 4-way random replacement cache for minimal active power consumption and wait states
- Ultra-low-power consumption with integrated sleep modes
- 48 MHz operation



9.3 Radio (RF Core)

The RF Core is a highly flexible and future proof radio module which contains an Arm Cortex-M0 processor that interfaces the analog RF and base-band circuitry, handles data to and from the system CPU side, and assembles the information bits in a given packet structure. The RF core offers a high level, command-based API to the main CPU that configurations and data are passed through. The Arm Cortex-M0 processor is not programmable by customers and is interfaced through the TI-provided RF driver that is included with the SimpleLink Software Development Kit (SDK).

The RF core can autonomously handle the time-critical aspects of the radio protocols, thus offloading the main CPU, which reduces power and leaves more resources for the user application. Several signals are also available to control external circuitry such as RF switches or range extenders autonomously.

Dual-band and multiprotocol solutions are enabled through time-sliced access of the radio, handled transparently for the application through the TI-provided RF driver and dual-mode manager.

The various physical layer radio formats are partly built as a software defined radio where the radio behavior is either defined by radio ROM contents or by non-ROM radio formats delivered in form of firmware patches with the SimpleLink SDKs. This allows the radio platform to be updated for support of future versions of standards even with over-the-air (OTA) updates while still using the same silicon.

注

Not all combinations of features, frequencies, data rates, and modulation formats described in this chapter are supported. Over time, TI can enable new physical radio formats (PHYs) for the device and provides performance numbers for selected PHYs in the data sheet. Supported radio formats for a specific device, including optimized settings to use with the TI RF driver, are included in the SmartRF Studio tool with performance numbers of selected formats found in tz p v a > 8.



9.3.1 Proprietary Radio Formats

The CC1354R10 radio can support a wide range of physical radio formats through a set of hardware peripherals combined with firmware available in the device ROM, covering various customer needs for optimizing towards parameters such as speed or sensitivity. This allows great flexibility in tuning the radio both to work with legacy protocols as well as customizing the behavior for specific application needs.

 $\frac{1}{8}$ 9-1 gives a simplified overview of features of the various radio formats available in ROM. Other radio formats may be available in the form of radio firmware patches or programs through the Software Development Kit (SDK) and may combine features in a different manner, as well as add other features.

主 0 1 Facture Cumpant

Feature	Main 2-(G)FSK Mode	High Data Rates	Low Data Rates	SimpleLink™ Long Range
Programmable preamble, sync word and CRC	Yes	Yes	Yes	No
Programmable receive bandwidth	Yes	Yes	Yes (down to 4 kHz)	Yes
Data / Symbol rate ⁽³⁾	20 to 1000 kbps	≤ 2 Msps	≤ 100 ksps	≤ 20 ksps
Modulation format	2-(G)FSK	2-(G)FSK 4-(G)FSK	2-(G)FSK 4-(G)FSK SUN-O-QPSK	2-(G)FSK
Dual Sync Word	Yes	Yes	No	No
Carrier Sense ⁽¹⁾ ⁽²⁾	Yes	No	No	No
Preamble Detection ⁽²⁾	Yes	Yes	Yes	No
Data Whitening	Yes	Yes	Yes	Yes
Digital RSSI	Yes	Yes	Yes	Yes
CRC filtering	Yes	Yes	Yes	Yes
Direct-sequence spread spectrum (DSSS)	No	No	No	1:2 1:4 1:8
Forward error correction (FEC)	No	No	No	Yes
Link Quality Indicator (LQI)	Yes	Yes	Yes	Yes

(1)	Carrier Sense can be used to implement HW-controlled listen-before-talk (LBT) and Clear Channel Assessment (CCA) for compliance
	with such requirements in regulatory standards. This is available through the CMD PROP CS radio API.

(2) Carrier Sense and Preamble Detection can be used to implement sniff modes where the radio is duty cycled to save power.

(3) Data rates are only indicative. Data rates outside this range may also be supported. For some specific combinations of settings, a smaller range might be supported.

9.3.2 Bluetooth 5.3 Low Energy

The RF Core offers full support for Bluetooth 5.3 Low Energy, including the high speed 2 Mbps physical layer and the 500 kbps and 125 kbps long range PHYs (Coded PHY) through the TI provided Bluetooth 5.3 stack or through a high-level Bluetooth API. The Bluetooth 5.3 PHY and part of the controller are in radio and system ROM, providing significant savings in memory usage and more space available for applications.

The new high-speed mode allows data transfers up to 2 Mbps, twice the speed of Bluetooth 4.2 and five times the speed of Bluetooth 4.0, without increasing power consumption. In addition to faster speeds, this mode offers significant improvements for energy efficiency and wireless coexistence with reduced radio communication time.

Bluetooth 5.3 also enables unparalleled flexibility for adjustment of speed and range based on application needs, which capitalizes on the high-speed or long-range modes respectively. Data transfers are now possible at 2 Mbps, enabling development of applications using voice, audio, imaging, and data logging that were not previously an option using Bluetooth low energy. With high-speed mode, existing applications deliver faster responses, richer engagement, and longer battery life. Bluetooth 5.3 enables fast, reliable firmware updates.



9.3.3 802.15.4 Thread, Zigbee, and 6LoWPAN

Through a dedicated IEEE radio API, the RF Core supports the 2.4 GHz IEEE 802.15.4-2011 physical layer (2 Mchips per second Offset-QPSK with DSSS 1:8), used in Thread, Zigbee, and 6LoWPAN protocols. The 802.15.4 PHY and MAC are in radio and system ROM. TI also provides royalty-free protocol stacks for Thread and Zigbee as part of the SimpleLink SDK, enabling a robust end-to-end solution.



9.4 Memory

The up to 1024 kB nonvolatile (Flash) memory provides storage for code and data. The flash memory is insystem programmable and erasable. The last flash memory sector must contain a Customer Configuration section (CCFG) that is used by boot ROM and TI provided drivers to configure the device. This configuration is done through the ccfg.c source file that is included in all TI provided examples.

The ultra-low leakage system static RAM (SRAM) is split into up to eight 32 kB blocks and can be used for both storage of data and execution of code. Retention of SRAM contents in Standby power mode is enabled by default and included in Standby mode power consumption numbers.Parity checking for detection of bit errors in memory is built-in, which reduces chip-level soft errors and thereby increases reliability. Parity can be disabled for an additional 32 kB which can be allocated for general purpose SRAM. System SRAM is always initialized to zeroes upon code execution from boot.

To improve code execution speed and lower power when executing code from nonvolatile memory, a 4-way nonassociative 8 kB cache is enabled by default to cache and prefetch instructions read by the system CPU. The cache can be used as a general-purpose RAM by enabling this feature in the Customer Configuration Area (CCFG).

There is a 4 kB ultra-low leakage SRAM available for use with the Sensor Controller Engine which is typically used for storing Sensor Controller programs, data and configuration parameters. This RAM is also accessible by the system CPU. The Sensor Controller RAM is not cleared to zeroes between system resets.

The ROM includes a TI-RTOS kernel and low-level drivers, as well as significant parts of selected radio stacks, which frees up flash memory for the application. The ROM also contains a serial (SPI and UART) bootloader that can be used for initial programming of the device.



9.5 Sensor Controller

The Sensor Controller contains circuitry that can be selectively enabled in both Standby and Active power modes. The peripherals in this domain can be controlled by the Sensor Controller Engine, which is a proprietary power-optimized CPU. This CPU can read and monitor sensors or perform other tasks autonomously; thereby significantly reducing power consumption and offloading the system CPU.

The Sensor Controller Engine is user programmable with a simple programming language that has syntax similar to C. This programmability allows for sensor polling and other tasks to be specified as sequential algorithms rather than static configuration of complex peripheral modules, timers, DMA, register programmable state machines, or event routing.

The main advantages are:

- Flexibility data can be read and processed in unlimited manners while still ensuring ultra-low power.
- 2 MHz low-power mode enables lowest possible handling of digital sensors
- Dynamic reuse of hardware resources
- · 40-bit accumulator supporting multiplication, addition and shift
- Observability and debugging options

Sensor Controller Studio is used to write, test, and debug code for the Sensor Controller. The tool produces C driver source code, which the System CPU application uses to control and exchange data with the Sensor Controller. Typical use cases may be (but are not limited to) the following:

- · Read analog sensors using integrated ADC or comparators
- Interface digital sensors using GPIOs, SPI, UART, or I²C (UART and I²C are bit-banged)
- Capacitive sensing
- Waveform generation
- Very low-power pulse counting (flow metering)
- Key scan

The peripherals in the Sensor Controller include the following:

- The low-power clocked comparator can be used to wake the system CPU from any state in which the comparator is active. A configurable internal reference DAC can be used in conjunction with the comparator. The output of the comparator can also be used to trigger an interrupt or the ADC.
- Capacitive sensing functionality is implemented through the use of a constant current source, a time-to-digital converter, and a comparator. The continuous time comparator in this block can also be used as a higheraccuracy alternative to the low-power clocked comparator. The Sensor Controller takes care of baseline tracking, hysteresis, filtering, and other related functions when these modules are used for capacitive sensing.
- The ADC is a 12-bit 200 ksps ADC with eight inputs and a built-in voltage reference. The ADC can be triggered by many different sources including timers, I/O pins, software, and comparators.
- · The analog modules can connect to up to eight different GPIOs
- Dedicated SPI master with up to 6 MHz clock speed

The peripherals in the Sensor Controller can also be controlled from the main application processor.



9.6 Cryptography

The CC1354R10 device comes with a wide set of modern cryptography-related hardware accelerators, drastically reducing code footprint and execution time for cryptographic operations. It also has the benefit of being lower power and improves availability and responsiveness of the system because the cryptography operations runs in a background hardware thread.

Together with a large selection of open-source cryptography libraries provided with the Software Development Kit (SDK), this allows for secure and future proof IoT applications to be easily built on top of the platform. The hardware accelerator modules are:

- **True Random Number Generator (TRNG)** module provides a true, nondeterministic noise source for the purpose of generating keys, initialization vectors (IVs), and other random number requirements. The TRNG is built on 24 ring oscillators that create unpredictable output to feed a complex nonlinear-combinatorial circuit
- Secure Hash Algorithm 2 (SHA-2) with support for SHA224, SHA256, SHA384, and SHA512
- Advanced Encryption Standard (AES) with 128, 192 and 256 bit key lengths
- Public Key Accelerator Hardware accelerator supporting mathematical operations needed for elliptic curves up to 512 bits

Through use of these modules and the TI provided cryptography drivers, the following capabilities are available for an application or stack:

- Key Agreement Schemes
 - Elliptic Curve Diffie–Hellman with static or ephemeral keys (ECDH and ECDHE)
 - Elliptic curve Password Authenticated Key Exchange by Juggling (ECJ-PAKE)
- Signature Processing
 - Elliptic curve Diffie-Hellman Digital Signature Algorithm (ECDSA)
 - Edwards-curve Digital Signature Algorithm (EdDSA)
- Curve Support
 - Short Weierstrass form, such as:
 - NIST-P224 (secp224r1), NIST-P256 (secp256r1), NIST-P384 (secp384r1), NIST-P521 (secp521r1)
 - Brainpool-256R1, Brainpool-384R1, Brainpool-512R1
 - Montgomery form, such as:
 - Curve25519
 - Twisted Edwards form, such as:
 - Ed25519
- Message Authentication Codes
 - AEC CBC-MAC
 - AES CMAC
 - HMAC with SHA224, SHA256, SHA384 and SHA512
- Block cipher mode of operation
- AES CCM and AES CCM-Star
- AES GCM
- AES ECB
- AES CBC
- AES CTR
- Hash Algorithm
 - SHA224
 - SHA256
 - SHA384
 - SHA512
- True random number generation

Other capabilities, such as RSA encryption and signatures (using keys as large as 2048 bits) as well as other ECC curves such as Curve1174, can be implemented using the provided public key accelerator but are not part of the TI SimpleLink SDK for the CC1354R10 device.



9.7 Timers

A large selection of timers are available as part of the CC1354R10 device. These timers are:

Real-Time Clock (RTC)

A 70-bit 3-channel timer running on the 32 kHz low frequency system clock (SCLK_LF). This timer is available in all power modes except Shutdown. The timer can be calibrated to compensate for frequency drift when using the LF RCOSC as the low frequency system clock. If an external LF clock with frequency different from 32.768 kHz is used, the RTC tick speed can be adjusted to compensate for this. When using TI-RTOS, the RTC is used as the base timer in the operating system and should thus only be accessed through the kernel APIs such as the Clock module. The real time clock can also be read by the Sensor Controller Engine to timestamp sensor data and also has dedicated capture channels. By default, the RTC halts when a debugger halts the device.

• General Purpose Timers (GPTIMER)

The four flexible GPTIMERs can be used as either 4× 32 bit timers or 8× 16 bit timers, all running on up to 48 MHz. Each of the 16- or 32-bit timers support a wide range of features such as one-shot or periodic counting, pulse width modulation (PWM), time counting between edges and edge counting. The inputs and outputs of the timer are connected to the device event fabric, which allows the timers to interact with signals such as GPIO inputs, other timers, DMA and ADC. The GPTIMERs are available in Active and Idle power modes.

Sensor Controller Timers

The Sensor Controller contains 3 timers:

The Sensor Controller contains 3 timers:AUX Timer 0 and 1 are 16-bit timers with a 2^N prescaler. Timers can either increment on a clock or on each edge of a selected tick source. Both one-shot and periodical timer modes are available.

AUX Timer 2 is a 16-bit timer that can operate at 24 MHz, 2 MHz or 32 kHz independent of the Sensor Controller functionality. There are 4 capture or compare channels, which can be operated in one-shot or periodical modes. The timer can be used to generate events for the Sensor Controller Engine or the ADC, as well as for PWM output or waveform generation.

Radio Timer

A multichannel 32-bit timer running at 4 MHz is available as part of the device radio. The radio timer is typically used as the timing base in wireless network communication using the 32-bit timing word as the network time. The radio timer is synchronized with the RTC by using a dedicated radio API when the device radio is turned on or off. This ensures that for a network stack, the radio timer seems to always be running when the radio is enabled. The radio timer is in most cases used indirectly through the trigger time fields in the radio APIs and should only be used when running the accurate 48 MHz high frequency crystal is the source of SCLK_HF.

Watchdog Timer

The watchdog timer is used to regain control if the system operates incorrectly due to software errors. It is typically used to generate an interrupt and reset the device for the case where periodic monitoring of the system components and tasks fails to verify proper functionality. The watchdog timer runs on a 1.5 MHz clock rate and cannot be stopped once enabled. The watchdog timer continues to run in Standby power mode but pauses when a debugger halts the device.

• Always On Watchdog Timer (AON_WDT)

The Always On Watchdog Timer is used during standby to regain control when the system has failed due to a software error or failure of an external device to respond in the expected way. It generates a reset when its configured time-out counter reaches zero and cannot be stopped once started, unless by asserting a device reset. The Always-on watchdog timer runs in Standby power mode and may pause when a debugger halts the device.



9.8 Serial Peripherals and I/O

The SPI interface provides a standardized synchronous serial interface to communicate with devices compatible with SPI (3 and 4 wire), MICROWIRE and TI Synchronous Serial Format. The SPIs support master/slave operation up to 12 MHz, programmable clock bit rate with prescaler, as well as configurable phase and polarity.

The UART interface implements universal asynchronous receiver and transmitter functions. The UART supports flexible baud-rate generation up to a maximum of 3 Mbps with FIFO, multiple data sizes, stop and parity bits as well as hardware handshake.

The I²S interface provides a standardized interface to exchange digital audio with devices compatible with this standard, including ADCs, DACs and CODECs. The I²S can also receive pulse-density modulation (PDM) data from devices such as digital microphones and perform conversion to PCM data.

The I²C interface enables low speed serial communications with devices compatible with the I²C standard. The I²C interface can handle both standard (100 kHz) and fast (400 kHz) speeds, as well as four modes of operation: master transmit/receive and slave transmit/receive.

The I/O controller (IOC) controls the digital I/O pins and contains multiplexer circuitry to allow a set of peripherals to be assigned to I/O pins in a flexible manner. All digital I/Os are interrupt and wake-up capable, have a programmable pullup and pulldown function, and can generate an interrupt on a negative or positive edge (configurable). When configured as an output, pins can function as either push-pull or open-drain. Five GPIOs have high-drive capabilities, which are marked in **bold** in $\forall 2 \neq \forall z \neq \vee 7$. All digital peripherals can be connected to any digital pin on the device.

9.9 Battery and Temperature Monitor

A combined temperature and battery voltage monitor is available in the CC1354R10 device. The battery and temperature monitor allows an application to continuously monitor on-chip temperature and supply voltage and respond to changes in environmental conditions as needed. The module contains window comparators to interrupt the system CPU when temperature or supply voltage go outside defined windows. These events can also be used to wake up the device from Standby mode through the Always-On (AON) event fabric.

9.10 µDMA

The device includes a direct memory access (μ DMA) controller. The μ DMA controller provides a way to offload data-transfer tasks from the system CPU, thus allowing for more efficient use of the processor and the available bus bandwidth. The μ DMA controller can perform a transfer between memory and peripherals. The μ DMA controller has dedicated channels for each supported on-chip module and can be programmed to automatically perform transfers between peripherals and memory when the peripheral is ready to transfer more data.

Some features of the µDMA controller include the following (this is not an exhaustive list):

- Highly flexible and configurable channel operation of up to 32 channels
- Transfer modes: memory-to-memory, memory-to-peripheral, peripheral-to-memory, and peripheral-to-peripheral
- · Data sizes of 8, 16, and 32 bits
- Ping-pong mode for continuous streaming of data

9.11 Debug

The debug subsystem implements two IEEE standards for debug and test purposes:

IEEE 1149.7 Class 4: Reduced-pin and Enhanced-functionality Test Access Port and Boundary-scan Architecture. This is known by the acronym cJTAG (compact JTAG) and this device uses only two pins to communicate to the target: TMS (JTAG_TMSC) and TCK (JTAG_TCKC). This is the default mode of operation.

IEEE standard 1149.1: Test Access Port and Boundary Scan Architecture Test Access Port (TAP). This standard is known by the acronym JTAG and this device uses four pins to communicate to the target: TMS (JTAG_TMSC), TCK (JTAG_TCKC), TDI (JTAG_TDI) and TDO (JTAG_TDO).



The debug subsystem also implements a user-configurable firewall to control unauthorized access to debug/test ports.



9.12 Power Management

To minimize power consumption, the CC1354R10 supports a number of power modes and power management features (see $\frac{1}{5}$ 9-2).

表 9-2. Power Modes					
MODE	SOFTV	VARE CONFIGURABLE	POWER MODES		RESET PIN
MODE	ACTIVE	IDLE	STANDBY	SHUTDOWN	HELD
CPU	Active	Off	Off	Off	Off
Flash	On	Available	Off	Off	Off
SRAM	On	On	Retention	Off	Off
Supply System	On	On	Duty Cycled	Off	Off
Register and CPU retention	Full	Full	Partial	No	No
SRAM retention	Full	Full	Full	No	No
48 MHz high-speed clock (SCLK_HF)	XOSC_HF or RCOSC_HF	XOSC_HF or RCOSC_HF	Off	Off	Off
2 MHz medium-speed clock (SCLK_MF)	RCOSC_MF	RCOSC_MF	Available	Off	Off
32 kHz low-speed clock (SCLK_LF)	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	Off	Off
Peripherals	Available	Available	Off	Off	Off
Sensor Controller	Available	Available	Available	Off	Off
Wake-up on RTC	Available	Available	Available	Off	Off
Wake-up on pin edge	Available	Available	Available	Available	Off
Wake-up on reset pin	On	On	On	On	On
Brownout detector (BOD)	On	On	Duty Cycled	Off	Off
Power-on reset (POR)	On	On	On	Off	Off
Watchdog timer (WDT)	Available	Available	Paused	Off	Off
Always-on Watchdog timer (AON_WDT)	Available	Available	Available	Off	Off

In **Active** mode, the application system CPU is actively executing code. Active mode provides normal operation of the processor and all of the peripherals that are currently enabled. The system clock can be any available clock source (see $\frac{1}{5}$ 9-2).

In **Idle** mode, all active peripherals can be clocked, but the Application CPU core and memory are not clocked and no code is executed. Any interrupt event brings the processor back into active mode.

In **Standby** mode, only the always-on (AON) domain is active. An external wake-up event, RTC event, or Sensor Controller event is required to bring the device back to active mode. MCU peripherals with retention do not need to be reconfigured when waking up again, and the CPU continues execution from where it went into standby mode. All GPIOs are latched in standby mode.

In **Shutdown** mode, the device is entirely turned off (including the AON domain and Sensor Controller), and the I/Os are latched with the value they had before entering shutdown mode. A change of state on any I/O pin defined as a *wake from shutdown pin* wakes up the device and functions as a reset trigger. The CPU can differentiate between reset in this way and reset-by-reset pin or power-on reset by reading the reset status register. The only state retained in this mode is the latched I/O state and the flash memory contents.



The Sensor Controller is an autonomous processor that can control the peripherals in the Sensor Controller independently of the system CPU. This means that the system CPU does not have to wake up, for example to perform an ADC sampling or poll a digital sensor over SPI, thus saving both current and wake-up time that would otherwise be wasted. The Sensor Controller Studio tool enables the user to program the Sensor Controller, control its peripherals, and wake up the system CPU as needed. All Sensor Controller peripherals can also be controlled by the system CPU.

注

The power, RF and clock management for the CC1354R10 device require specific configuration and handling by software for optimized performance. This configuration and handling is implemented in the TI-provided drivers that are part of the CC1354R10 software development kit (SDK). Therefore, TI highly recommends using this software framework for all application development on the device. The complete SDK with TI-RTOS (optional), device drivers, and examples are offered free of charge in source code.

9.13 Clock Systems

The CC1354R10 device has several internal system clocks.

The 48 MHz SCLK_HF is used as the main system (MCU and peripherals) clock. This can be driven by the internal 48 MHz RC Oscillator (RCOSC_HF) or an external 48 MHz crystal (XOSC_HF). Radio operation requires an external 48 MHz crystal.

SCLK_MF is an internal 2 MHz clock that is used by the Sensor Controller in low-power mode and also for internal power management circuitry. The SCLK_MF clock is always driven by the internal 2 MHz RC Oscillator (RCOSC_MF).

SCLK_LF is the 32.768 kHz internal low-frequency system clock. It can be used by the Sensor Controller for ultra-low-power operation and is also used for the RTC and to synchronize the radio timer before or after Standby power mode. SCLK_LF can be driven by the internal 32.8 kHz RC Oscillator (RCOSC_LF), a 32.768 kHz watch-type crystal, or a clock input on any digital IO.

When using a crystal or the internal RC oscillator, the device can output the 32 kHz SCLK_LF signal to other devices, thereby reducing the overall system cost.

9.14 Network Processor

Depending on the product configuration, the CC1354R10 device can function as a wireless network processor (WNP - a device running the wireless protocol stack with the application running on a separate host MCU), or as a system-on-chip (SoC) with the application and protocol stack running on the system CPU inside the device.

In the first case, the external host MCU communicates with the device using SPI or UART. In the second case, the application must be written according to the application framework supplied with the wireless protocol stack.



10 Application, Implementation, and Layout

注

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

For general design guidelines and hardware configuration guidelines, refer to CC13xx/CC26xx Hardware Configuration and PCB Design Considerations Application Report.

10.1 Reference Designs

The following reference designs should be followed closely when implementing designs using the CC1354R10 device.

Special attention must be paid to RF component placement, decoupling capacitors and DCDC regulator components, as well as ground connections for all of these.

CC1352REM-XD7793-XD24 Design Files	The CC1352REM-XD7793-XD24 reference design provides schematic, layout and production files for the characterization board used for deriving the performance number found in this document.
LP-EM-CC1354P10-1 Design Files	Detailed schematics and layouts for the multi-band CC1354P10 LaunchPad evaluation board featuring 868/915 MHz RF matching on the 20 dBm PA output and up to 5 dBm TX power at 2.4 GHz.
LP-EM-CC1354P10-6 Design Files	Detailed schematics and layouts for the multi-band CC1354P10 LaunchPad evaluation board featuring 2.4 GHz RF matching optimized for 10 dBm operation on the 20 dBm PA output and up to 13 dBm TX power at 433 MHz.
Sub-1 GHz and 2.4 GHz Antenna Kit for LaunchPad ™ Development Kit and SensorTag	 The antenna kit allows real-life testing to identify the optimal antenna for your application. The antenna kit includes 16 antennas for frequencies from 169 MHz to 2.4 GHz, including: PCB antennas Helical antennas Chip antennas

• Dual-band antennas for 868 MHz and 915 MHz combined with 2.4 GHz

The antenna kit includes a JSC cable to connect to the Wireless MCU LaunchPad Development Kits and SensorTags.



10.2 Junction Temperature Calculation

This section shows the different techniques for calculating the junction temperature under various operating conditions. For more details, see Semiconductor and IC Package Thermal Metrics.

There are three recommended ways to derive the junction temperature from other measured temperatures:

1. From package temperature:

$$T_J = \psi_{\rm JT} \times P + T_{\rm case} \tag{1}$$

2. From board temperature:

$$T_J = \psi_{\rm JB} \times P + T_{\rm board} \tag{2}$$

3. From ambient temperature:

$$T_J = R_{\Theta JA} \times P + T_A \tag{3}$$

P is the power dissipated from the device and can be calculated by multiplying current consumption with supply voltage. Thermal resistance coefficients are found in $\frac{1}{2}223 \times 8.8$.

$$T_J = 23.4^{\circ}C/_W \times 51.8mW + T_A = 1.2^{\circ}C + T_A \tag{4}$$

For various application use cases current consumption for other modules may have to be added to calculate the appropriate power dissipation. For example, the MCU may be running simultaneously as the radio, peripheral modules may be enabled, etc. Typically, the easiest way to find the peak current consumption, and thus the peak power dissipation in the device, is to measure as described in Measuring CC13xx and CC26xx current consumption.



11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed as follows.

11.1 Tools and Software

The CC1354R10 device is supported by a variety of software and hardware development tools.

Development Kit

CC1354P10-1 LaunchPad™ Development Kit

The CC1354P10-1 LaunchPad [™] Development Kit enables development of highperformance wireless applications in the 863 - 930 MHz and 2.4 GHz frequency bands that benefit from low-power operation. The kit features the CC1354P10 multi-band and multiprotocol SimpleLink Wireless MCU with an integrated High-Power Amplifier. The kit works with the LaunchPad ecosystem, easily enabling additional functionality like sensors, display, and more.

The RF configuration of the LaunchPad enables up to +20 dBm output power for 863 to 930 MHz and +5 dBm output power for 2.4 GHz.

CC1354P10-6 LaunchPad™ Development Kit

LP-XDS110

LaunchPad™

Debug Probe

The CC1354P10-6 LaunchPad [™] Development Kit enables development of highperformance wireless applications in the 863 - 930 MHz and 2.4 GHz frequency bands that benefit from low-power operation. The kit features the CC1354P10 multi-band and multiprotocol SimpleLink Wireless MCU with an integrated High-Power Amplifier. The kit works with the LaunchPad ecosystem, easily enabling additional functionality like sensors, display, and more. The built-in EnergyTrace[™] software is an energy-based code analysis tool that measures and displays the application's energy profile and helps to optimize it for ultra-low power consumption.

The RF configuration of the LaunchPad enables up to +14 dBm output power for 863 to 930 MHz and +20 dBm output power for 2.4 GHz.

The LP-XDS110 LaunchPad[™] Debug Probe enables development of high-performance wireless applications in the entire family of LP-EM LaunchPad[™] development boards. Featuring a seamless connection with the new 20-pin LP-EM Debug connector, it supports not only multiple standards such as JTAG/cJTAG/SWD but also a UART backchannel for maximum debugging flexibility. It also features an Arm[®] 10-pin Debug connector to perform debugging in any custom board.

LP-XDS110ET LaunchPad[™] Debug Probe The LP-XDS110ET LaunchPad[™] Debug Probe enables development of high-performance wireless applications in the entire family of LP-EM LaunchPad[™] development boards. Featuring a seamless connection with the new 20-pin LP-EM Debug connector, it supports not only multiple standards such as JTAG/cJTAG/SWD but also a UART backchannel for maximum debugging flexibility. In addition, it also features an Arm[®] 10-pin Debug connector to perform debugging in any custom board. This Debug Probe also features the XDS110 EnergyTrace[™] technology, which is a new method for measuring the current consumption that captures the complete operational profile of the wireless MCU.

TMDSEMU110-U Debug Probe The TMDSEMU110-U Debug Probe enables development of high-performance wireless applications in the entire family of SimpleLink LaunchPad[™] development boards. Featuring a convenient enclosure, which grants the proper mechanical robustness for field and production environments, it supports not only multiple standards such as JTAG/cJTAG/SWD but also a UART backchannel and four GPIOs for maximum debugging flexibility. In addition, the expansion connector allows using the TMDSEMU110-ETH add-on (sold separately), which adds the full featured XDS110 EnergyTrace[™] technology with variable

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supply voltage from 1.8V to 3.6V and up to 800 mA of supply current. The XDS110 EnergyTrace[™] technology is a new method for measuring the current consumption that captures the complete operational profile of the wireless MCU.



SimpleLink™ LOWPOWER F2 SDK

The SimpleLink LOWPOWER F2 Software Development Kit (SDK) provides a complete package for the development of wireless applications on the CC13XX / CC26XX family of devices. The SDK includes a comprehensive software package for the CC1354R10 device, including the following protocol stacks:

- Bluetooth Low Energy 4 and 5.3
- Thread (based on OpenThread)
- TI Z-Stack (Zigbee 3.0)
- TI 15.4-Stack an IEEE 802.15.4-based star networking solution for Sub-1 GHz and 2.4 GHz
- EasyLink a large set of building blocks for building proprietary RF software stacks
- Multiprotocol support concurrent operation between stacks using the Dynamic Multiprotocol Manager (DMM)
- TI Wi-SUN FAN Stack
- Matter

The SimpleLink LOWPOWER F2 SDK is part of TI's SimpleLink MCU platform, offering a single development environment that delivers flexible hardware, software and tool options for customers developing wired and wireless applications. For more information about the SimpleLink MCU Platform, visit ti.com/simplelink.

Development Tools

Code Composer Studio[™] Integrated Development Environment (IDE)

Code Composer Studio is an integrated development environment (IDE) that supports TI's Microcontroller and Embedded Processors portfolio. Code Composer Studio comprises a suite of tools used to develop and debug embedded applications. It includes an optimizing C/C++ compiler, source code editor, project build environment, debugger, profiler, and many other features. The intuitive IDE provides a single user interface taking you through each step of the application development flow. Familiar tools and interfaces allow users to get started faster than ever before. Code Composer Studio combines the advantages of the Eclipse[®] software framework with advanced embedded debug capabilities from TI resulting in a compelling feature-rich development environment for embedded developers.

CCS has support for all SimpleLink Wireless MCUs and includes support for EnergyTrace[™] software (application energy usage profiling). A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK.

Code Composer Studio is provided free of charge when used in conjunction with the XDS debuggers included on a LaunchPad Development Kit.

Code Composer Studio[™] Cloud IDE Code Composer Studio (CCS) Cloud is a web-based IDE that allows you to create, edit and build CCS and Energia[™] projects. After you have successfully built your project, you can download and run on your connected LaunchPad. Basic debugging, including features like setting breakpoints and viewing variable values is now supported with CCS Cloud.

IAR Embedded Workbench[®] for Arm[®] IAR Embedded Workbench[®] is a set of development tools for building and debugging embedded system applications using assembler, C and C++. It provides a completely integrated development environment that includes a project manager, editor, and build tools. IAR has support for all SimpleLink Wireless MCUs. It offers broad debugger support, including XDS110, IAR I-jet[™] and Segger J-Link[™]. A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK. IAR is also supported out-of-the-box on most software examples provided as part of the SimpleLink SDK.

A 30-day evaluation or a 32 kB size-limited version is available through iar.com.



- SmartRF[™] Studio SmartRF[™] Studio is a Windows[®] application that can be used to evaluate and configure SimpleLink Wireless MCUs from Texas Instruments. The application will help designers of RF systems to easily evaluate the radio at an early stage in the design process. It is especially useful for generation of configuration register values and for practical testing and debugging of the RF system. SmartRF Studio can be used either as a standalone application or together with applicable evaluation boards or debug probes for the RF device. Features of the SmartRF Studio include:
 - Link tests send and receive packets between nodes
 - · Antenna and radiation tests set the radio in continuous wave TX and RX states
 - · Export radio configuration code for use with the TI SimpleLink SDK RF driver
 - Custom GPIO configuration for signaling and control of external switches

Sensor Controller Studio Sensor Controller Studio is used to write, test and debug code for the Sensor Controller peripheral. The tool generates a Sensor Controller Interface driver, which is a set of C source files that are compiled into the System CPU application. These source files also contain the Sensor Controller binary image and allow the System CPU application to control and exchange data with the Sensor Controller. Features of the Sensor Controller Studio include:

- Ready-to-use examples for several common use cases
- Full toolchain with built-in compiler and assembler for programming in a C-like programming language
- Provides rapid development by using the integrated sensor controller task testing and debugging functionality, including visualization of sensor data and verification of algorithms

UniFlash UniFlash is a standalone tool used to program on-chip flash memory on TI MCUs. UniFlash has a GUI, command line, and scripting interface. UniFlash is available free of charge.

11.1.1 SimpleLink[™] Microcontroller Platform

The SimpleLink microcontroller platform sets a new standard for developers with the broadest portfolio of wired and wireless Arm[®] MCUs (System-on-Chip) in a single software development environment. Delivering flexible hardware, software and tool options for your IoT applications. Invest once in the SimpleLink software development kit and use throughout your entire portfolio. Learn more on ti.com/simplelink.

11.2 Documentation Support

To receive notification of documentation updates on data sheets, errata, application notes and similar, navigate to the device product folder on ti.com/product/CC1354R10. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

The current documentation that describes the MCU, related peripherals, and other technical collateral is listed as follows.

TI Resource Explorer

TI Resource Explorer Software examples, libraries, executables, and documentation are available for your device and development board.

Errata

CC1354R10 Silicon Errata

The silicon errata describes the known exceptions to the functional specifications for each silicon revision of the device and description on how to recognize a device revision.



All application reports for the CC1354R10 device are found on the device product folder at: ti.com/product/ CC1354R10/technicaldocuments.

Technical Reference Manual (TRM)

CC13x4, CC26x4 SimpleLink™ Wireless MCU Technical Reference Manual

The TRM provides a detailed description of all modules and peripherals available in the device family.

11.3 サポート・リソース

TI E2E[™] サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接 得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計で必要な支援を迅速に得るこ とができます。

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11.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずか に変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

11.6 用語集

テキサス・インスツルメンツ用語集

この用語集には、用語や略語の一覧および定義が記載されています。



12 Mechanical, Packaging, and Orderable Information

12.1 Packaging Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

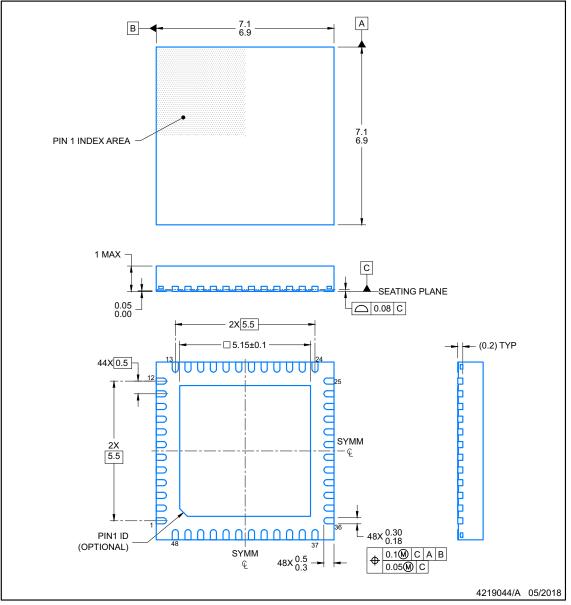
注

The RSK (S-PQVFN-N64) package drawings in this datasheet are preliminary and will change for the production release of this IC. The change will be related to the exposed thermal pad size of the IC. The current sample has a 3.7 mm x 3.7 mm thermal ground pad. Production devices will have a 4.7 mm x 4.7mm thermal ground pad. It is recommended to design the thermal ground pad to be 4.7 mm x 4.7 mm, with a stencil opening of 3.7 mm x 3.7mm for pre-production devices. For production devices, only the stencil will need to change to 4.7 mm x 4.7 mm. No change to the PCB will be required.

RGZ0048A

PACKAGE OUTLINE VQFN - 1 mm max height

PLASTIC QUADFLAT PACK- NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

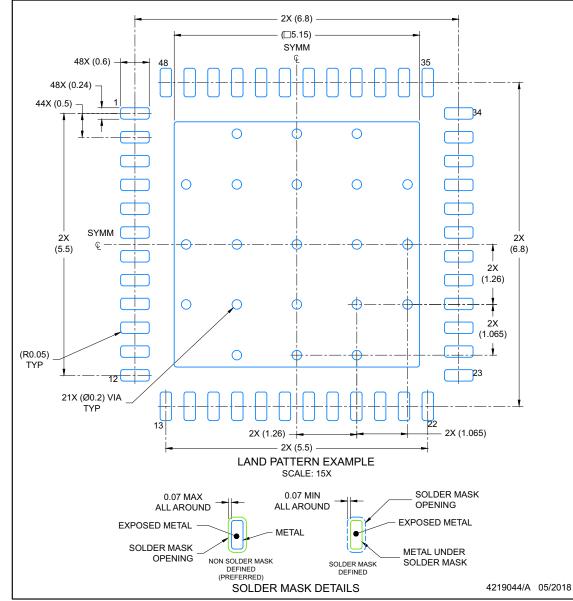




EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUADFLAT PACK- NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



English Data Sheet: SWRS266



RGZ0048A

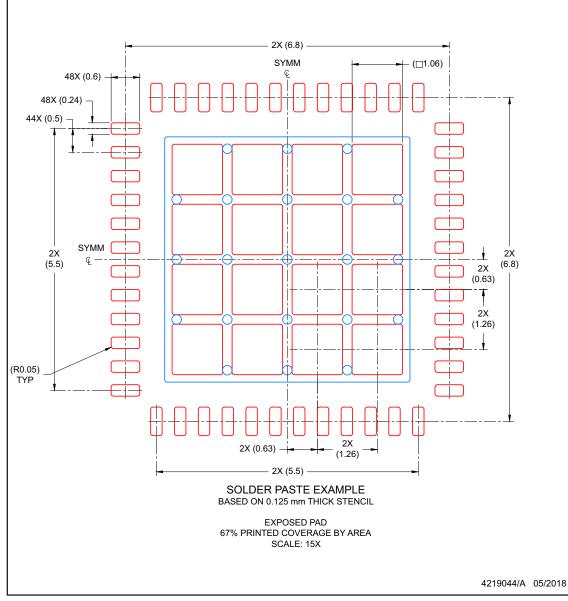


EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

RGZ0048A





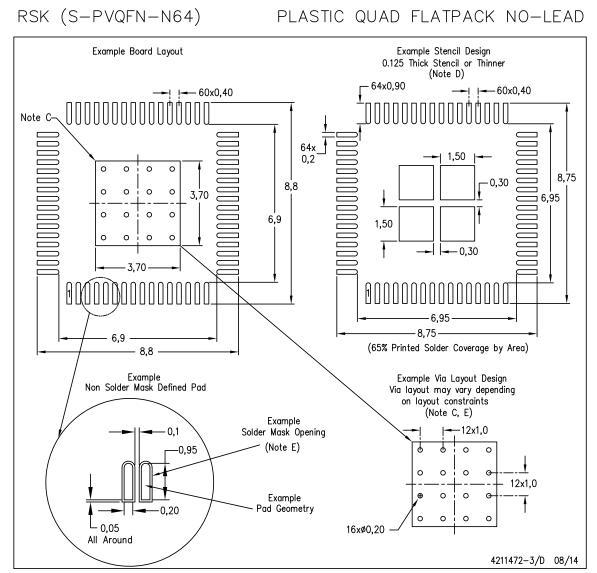
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





LAND PATTERN DATA

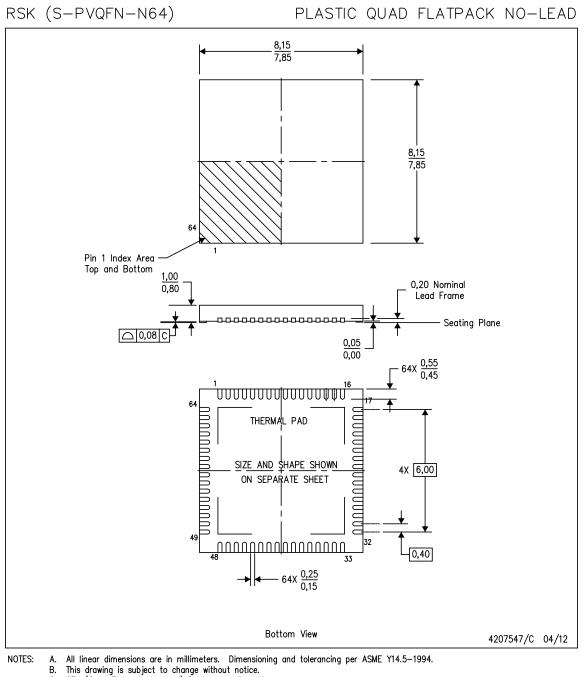


- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting
 - E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tent recommendations for any larger diameter vias placed in the thermal pad.





MECHANICAL DATA

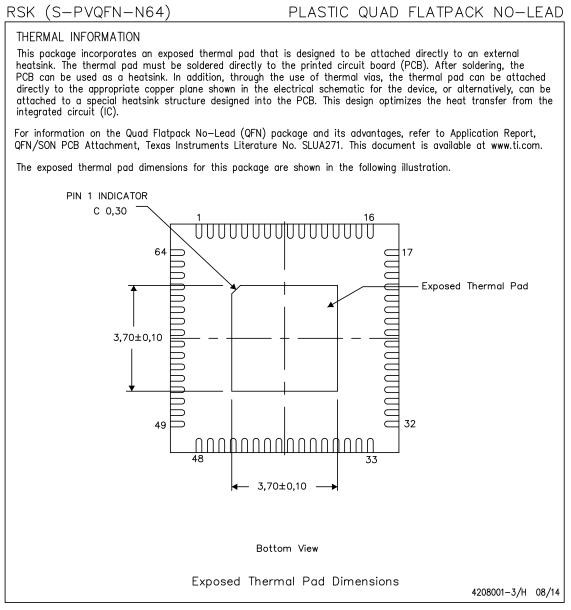


- This drawing is subject to change without notice.
- C. D. E.
- QFN (Quad Flatpack No-Lead) Package configuration. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.





THERMAL PAD MECHANICAL DATA



NOTE: A. All linear dimensions are in millimeters





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
XCC1354R106T0RGZ	ACTIVE	VQFN	RGZ	48	4000	TBD	Call TI	Call TI	-40 to 105		Samples
XCC1354R106T0RSK	ACTIVE	VQFN	RSK	64	4000	TBD	Call TI	Call TI	-40 to 105		Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

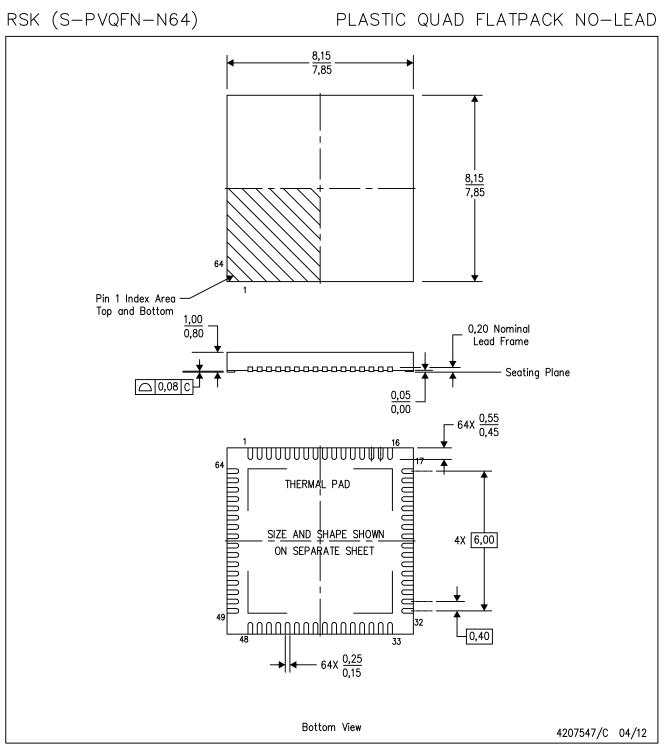
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www.ti.com

PACKAGE OPTION ADDENDUM



NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994. A.

- This drawing is subject to change without notice. Β.
- C.
- QFN (Quad Flatpack No-Lead) Package configuration. The package thermal pad must be soldered to the board for thermal and mechanical performance. D.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.



RGZ 48

7 x 7, 0.5 mm pitch

GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUADFLAT PACK- NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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